

Chapter I

Diode Circuits

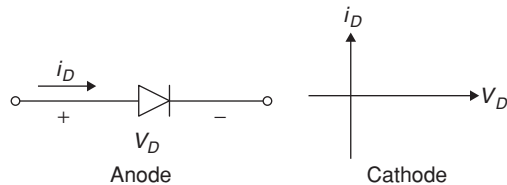
LEARNING OBJECTIVES

After reading this chapter, you will be able to understand:

- Small signal equivalent circuit of diode
- Practical PN junction diode
- Large signal diode-models
- Open circuit test
- Short circuit test
- Rectifiers
- Half wave rectifier analysis
- Full wave rectifier
- Peak inverse voltage
- Bridge rectifier
- Clipping circuits
- Clamper circuits
- Voltage multipliers
- Power supplies
- Voltage regulators

SMALL SIGNAL EQUIVALENT CIRCUIT OF DIODE

An ideal diode is a two-element device which has the circuit symbol and Volt-ampere characteristic as shown below:



A diode is a two-terminal unipolar device which provides minimum resistance in the forward direction and maximum resistance in the reverse direction.

Ideal diode is an unilateral circuit element, as the current in the device is in one direction only. This behavior is important in switching as it provides an ON-OFF characteristic.

Practical PN Junction Diode

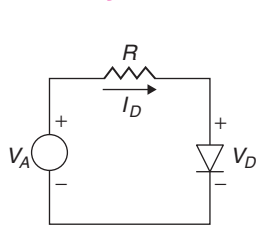


Figure 1 Diode circuit

From the circuit, $-V_A + I_D R + V_D = 0$ (KVL) $I_D = \frac{-1}{R} V_D + \frac{V_A}{R} A$

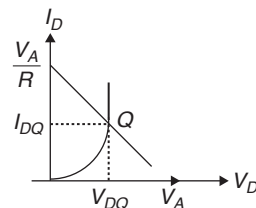


Figure 2 Diode characteristic and load line

This equation defines a straight line, called load line. The load line and diode characteristic must be satisfied simultaneously, at their point of intersection Q , called Quiescent or operating point. The values of current in and voltage across the diode are denoted by I_{DQ} and V_{DQ} respectively.

Large Signal Diode-Models

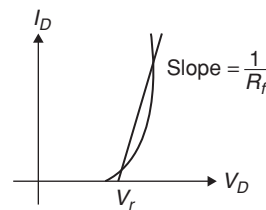


Figure 3 Piecewise linear diode forward characteristic

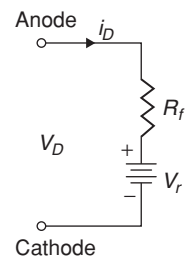


Figure 4 Diode model for forward bias

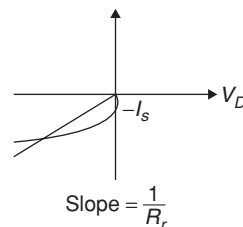


Figure 5 Piecewise linear reverse based characteristic diode

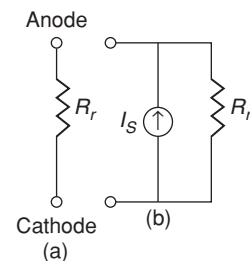


Figure 6 Diode model on piecewise linear representation (b) Model to include surface leakage

Model	Equivalent Circuit	V-I characteristics
Ideal		
Simplified model		
Piecewise linear model		

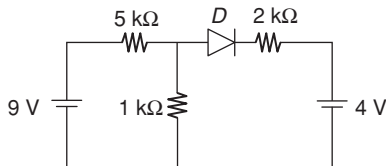
Open circuit test

- Replace the diode with open Circuit
- Find the voltage across the diode from 'p' to 'n' side, if it is positive, diode is in Forward Biased. If it is negative, diode is in Reverse Biased.

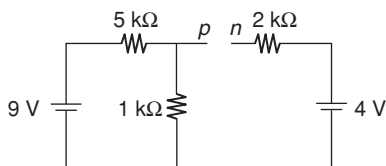
Short circuit test

- Replace all the diodes with short Circuit
- Find the current through the diode from 'p' to 'n' side say ' I '.
If $I > 0$, Diode is in forward biased
If $I < 0$, Diode is in reverse biased

Example 1: Check whether the diode is in forward biased or not?



Solution: 'D' is open



$$V_p = \frac{9}{6} = 1.5 \text{ V}$$

$$V_n = 4 \text{ V}$$

$$V_p < V_n$$

Hence 'D' is in reverse biased condition.

ELEMENTARY DIODE APPLICATIONS

Rectifiers

A device, such as the semiconductor diode, which is capable of converting a sinusoidal input waveform into a

unidirectional waveform with a non-zero average component is called rectifier.

Half wave rectifier

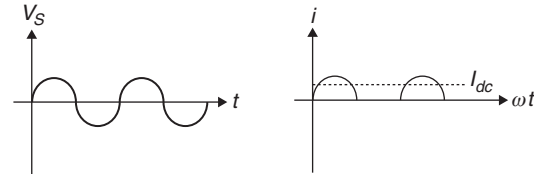


Figure 7 Volt (V_s) and current (i) waveforms

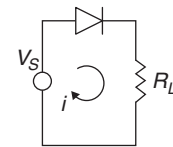


Figure 8 Half wave rectifier

During the first half of cycle (positive cycle). The diode is ON, and current $\frac{V_s}{R_L}$ exists. The diode is off during negative half cycle of V_s so that the current is zero as the current exists for only one half cycle, it is called halfwave rectifier.

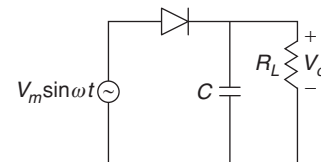


Figure 9 Rectifier with capacitor filter

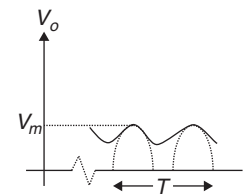


Figure 10 Output voltage waveform

The circuit uses a capacitor 'C' as a simple filter to convert the waveform to the nearly constant (DC) level. If the time constant $R_L C$ is much greater than the time period of T of input waveforms, the discharge will be slow.

The peak to peak ripple out of any capacitor input filter

$$\text{is } V_R = \frac{I}{fC}$$

V_R – peak to peak ripple voltage

I – DC load current

f – ripple frequency

C – capacitance

$$V_{rms} = \frac{V_{PP}}{2\sqrt{2}}$$

If we use real diode, the equivalent circuit is as shown in Figure 11.

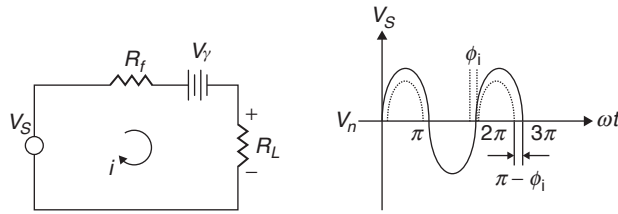


Figure 11 Rectifier equivalent circuit

The current ' i ' is obtained by KVL

$$i = \frac{V_s - V_\gamma}{R_L} = \frac{V_m \sin \omega t - V_\gamma}{R_L}$$

as it is greater than zero only when $V_s > V_\gamma$. Thus current waveform does not start when $\omega t = 0$, but has a cut in or ignition angle ϕ , given by $\phi_i = \sin^{-1}\left(\frac{V_\gamma}{V_m}\right)$.

Similarly extinction angle exists at the end of positive cycle its value is $\pi - \phi_i$.

Half Wave Rectifier Analysis

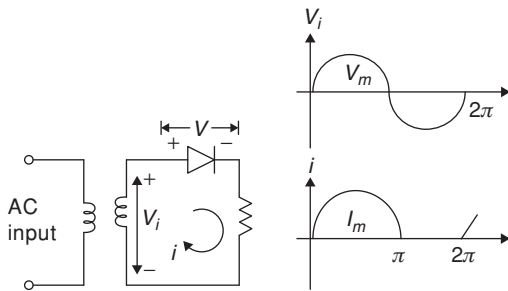


Figure 12 Basic circuit of half wave rectifier

$V_i = V_m \sin \omega t$, has peak value of V_m , which is mostly very high when compared to V_γ of diode, assume $V_\gamma = 0$.

The diode idealized to be a resistance R_f in the ON state, and an open circuit in the OFF state, the current in the diode or load R_L is

$$i = I_m \sin \omega t \text{ if } 0 \leq \omega t \leq \pi \\ = 0, \text{ if } \pi \leq \omega t \leq 2\pi$$

And
$$I_m = \frac{V_m}{R_f + R_L}$$

DC current of value (Average current)

$$I_{DC} = \frac{1}{2\pi} \int_0^{2\pi} i d(\omega t)$$

For half wave circuit,
$$I_{DC} = \frac{1}{2\pi} \int_0^\pi I_m \sin(\omega t) d(\omega t) = \frac{I_m}{\pi}$$

The DC (average) output voltage is given as

$$V_{DC} = I_{DC} \cdot R_L = \frac{I_m R_L}{\pi} = \frac{V_m}{\pi}$$

The DC voltage across diode is not given by $I_{DC} R_f$, as diode acts as resistance which has two values

R_f in the ON state, and ∞ in the OFF state

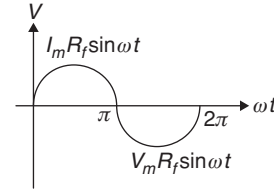


Figure 13 Voltage across the diode

$$\begin{aligned} \text{So } V_{DC} &= \frac{1}{2\pi} \left[\int_0^\pi I_m R_f \sin \omega t d(\omega t) + \int_\pi^{2\pi} -V_m R_f \sin(\omega t) d(\omega t) \right] \\ &= \frac{1}{\pi} (I_m R_f - V_m) \\ &= \frac{1}{\pi} [I_m R_f - I_m (R_f + R_L)] \end{aligned}$$

$V_{DC} = \frac{-I_m R_L}{\pi}$, so the DC diode voltage is seen to be equal to the negative of average voltage across the load resistor.

The AC current
$$I_{rms} = \left(\frac{1}{2\pi} \int_0^{2\pi} i^2 d(\omega t) \right)^{1/2} = \frac{I_m}{2}$$

$$V_{rms} = I_{rms} R_L$$

$$V_{rms} = \frac{I_m}{2} R_L = \frac{V_m}{2}$$

Regulation

The variation of DC output voltage as a function of DC load current is called regulation.

$$\% \text{ of regulation} = \frac{V_{\text{no load}} - V_{\text{load}}}{V_{\text{load}}} \times 100\%$$

No load refers to zero current, load indicates the normal load current

Note: ideal power supply has percentage regulation zero

$$I_{DC} = \frac{I_m}{\pi} = \frac{V_m / \pi}{R_f + R_L}, \quad V_{DC} = I_{DC} R_L$$

The DC output voltage varies as

$$V_{DC} = \frac{V_m}{\pi} - I_{DC} R_f$$

Full wave rectifier

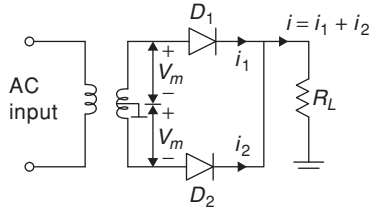


Figure 14 A full wave rectifier circuit

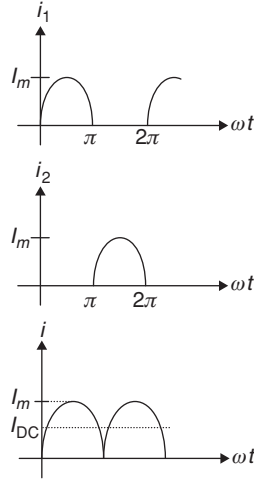


Figure 15 The diode currents i_1 and i_2 and load current i , output voltage $V_o = iR_L$

The circuit, is seen to comprise of two half wave rectifiers, connected so that conduction takes place through one of the diodes at one half cycle.

$$I_{DC} = \frac{2I_m}{\pi}$$

$$I_{rms} = \frac{I_m}{\sqrt{2}}$$

$$V_{DC} = \frac{2I_m R_L}{\pi}$$

$$V_{DC} = \frac{2V_m}{\pi} - I_{DC} R_f$$

If we include V_γ , of the diode

$$\theta_1 = \sin^{-1} \frac{V_\gamma}{V_m}, \theta_2 = \pi - \theta_1$$

The average current I_{DC}

$$I_{DC} = \frac{V_m}{\pi(R_f + R_L)} \cos \theta_1 - \frac{\pi - 2\theta_1}{2\pi} \frac{V_\gamma}{R_f + R_L} \quad (\text{half wave rectifier})$$

$$I_{DC} = \frac{2V_m}{\pi(R_f + R_L)} \cos \theta_1 - \frac{\pi - 2\theta_1}{2\pi} \frac{V_\gamma}{R_f + R_L} \quad (\text{full wave rectifier})$$

Example 2: A diode with an internal resistance of 10Ω is used as a rectifier to supply power to a 500Ω load from a 220 V (rms) source of supply. Calculate (a) the peak load current (b) the DC load current (c) the rms load current (d) the DC diode voltage (e) the total input power to the circuit (f) percentage regulation from no-load to the given load.

Solution: A diode is used as rectifier, so half wave rectifier, if two diodes are used, it will be full wave rectifier.

$$(a) \quad I_m = \frac{V_m}{R_f + R_L} = \frac{\sqrt{2}V_{rms}}{R_f + R_L} = \frac{\sqrt{2} \cdot 220}{(10 + 500)}$$

$$= 0.61 \text{ A}$$

$$(b) \quad I_{DC} = \frac{I_m}{\pi} = 0.19 \text{ A}$$

$$(c) \quad I_{rms} = \frac{I_m}{2} = 0.305 \text{ A}$$

$$(d) \quad V'_{DC} = \frac{I_m R_L}{\pi} = -0.61 \times \frac{500}{\pi}$$

$$= -97.1 \text{ V}$$

$$(e) \quad \text{Power delivered} = V_{rms} I_{rms}$$

$$= (220 \text{ V}) (0.305 \text{ A}) = 67.1 \text{ W}$$

$$(f) \quad \% \text{ regulation} = \frac{I_{DC} R_L}{\frac{V_m}{\pi} - I_{DC} R_f} \times 100$$

$$= \frac{\frac{V_m}{\pi(R_f + R_L)} \cdot R_f}{\left(\frac{V_m}{\pi} - \frac{V_m}{\pi(R_f + R_L)} R_f \right)} \times 100$$

$$= \frac{R_f}{R_L} \times 100$$

As R_L goes from ∞ (no-load) to 500Ω , percentage regulation will go from 0 to 2%.

Peak Inverse Voltage

For each rectifier circuit there is a maximum voltage to which the diode can be subjected. This potential is called peak inverse voltage (PIV). For half wave rectifier, the peak inverse voltage is V_m and for full wave rectifier PIV is $2V_m$. In full wave circuit, independent of the filter used, the PIV across each diode is twice the maximum transformer voltage (center tap to other end).

Peak inverse voltage is the maximum voltage across the non-conducting diode of rectifier, the voltage must be less than the break down voltage of the diode otherwise the diode will be destroyed.

PIV of half wave rectifier with capacitor input filter $PIV = 2V_m$.

Bridge rectifier with capacitor input filter, $PIV = V_m$

Bridge rectifier

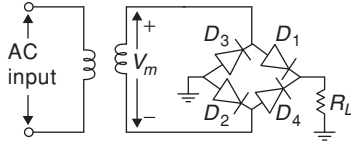


Figure 16 A Bridge rectifier

The bridge rectifier is similar to a full wave rectifier because it produces a full wave output voltage, diodes D_1 and D_2 conduct on the positive half cycle and D_3 and D_4 conduct on the negative half cycle. As result rectified output flows during both half cycles.

Features

- The current drawn in both the primary and the secondary of the supply transformer are sinusoidal, and therefore a smaller transformer may be used than for the full wave circuit for the same input.
- A transformer without center tap is used.

The advantage of this type of full wave rectification over the center tapped version in the conventional full wave rectifier, is entire secondary voltage of transformer can be used DC output

$$(V) = \frac{2V_m}{\pi}$$

$$I_{DC} = \frac{2I_m}{\pi}$$

$$\text{Current through each diode} = I_{\text{diode}} = \frac{I_{DC}}{2}$$

Example 3: In a bridge rectifier, the input AC source has an amplitude of 5 V, and the load resistance is 100 Ω . The diodes have an on resistance of 10 Ω , $V_r = 0.6$ V. The DC output voltage is ____

- (A) 1.69 V (B) 1.81 V
(C) 2.35 V (D) 2.38 V

Solution: (A)

$$V_{DC} = 2 \left[\frac{V_m R_L}{\pi (R_F + R_L)} - V_r \right]$$

$$\cong 2 \left[\frac{5}{\pi} \frac{100}{(100 + 10)} - 0.6 \right] = 1.69$$

Table 1 Unfiltered rectifiers

	Half Wave	Full Wave	Bridge
Number of diodes	1	2	4
Peak output ideal	V_m	$\frac{V_m}{2}$ (center tapped)	V_m
Peak output (practical)	$V_m - 0.7$ V	$\frac{V_m}{2} - 0.7$ V	$V_m - 1.4$ V
DC output	$V_p(\text{out})/\pi$	$2 V_p(\text{out})/\pi$	$\frac{2 V_p(\text{out})}{\pi}$
Ripple frequency	f_{in}	$2f_{in}$	$2f_{in}$

V_m – peak secondary voltage

$V_p(\text{out})$ – peak output voltage

Voltage multiplier

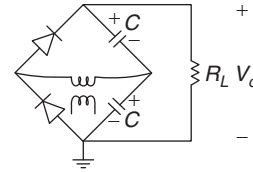
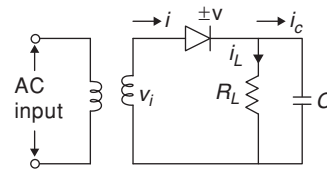


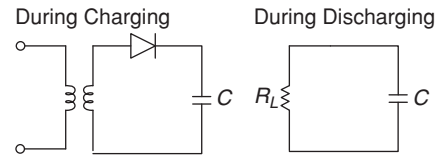
Figure 17 Bridge rectifier as voltage doubler

A common voltage doubling circuit which delivers a dc voltage approximately, equal to twice the transformer maximum voltage at no load. The circuit is operated by alternately charging each of two capacitors, to the transformer peak voltage V_m , current being continuously drained from capacitors through load. The capacitors also act to smooth out the ripple in the output.

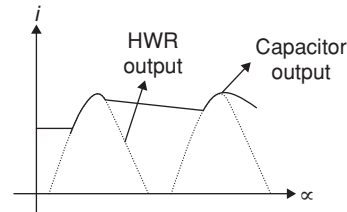
Capacitor filters



Capacitor stores the energy during the conduction period and delivers this energy to the load during non-conducting.



Diode having less forward resistance, and capacitor charges very fastly and the value of R_L is designed to be so high to get the small ripple at the output



Full wave rectifier with a capacitor filter is obtained by placing a capacitor 'C' across R_L

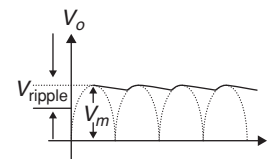


Figure 18 Approximate load voltage waveform for full wave rectifier with capacitive filter

The average value of the voltage is approximately

$$V_{DC} = V_m - \frac{V_{\text{ripple}}}{2}$$

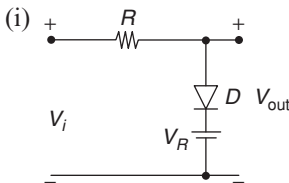
$$V_{\text{ripple}} = \frac{I_{DC}}{2fC} \quad (\text{for full wave rectifier})$$

$$V_{DC} = V_m - \frac{I_{DC}}{4fC}$$

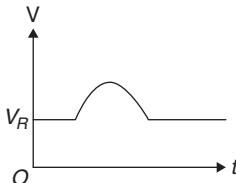
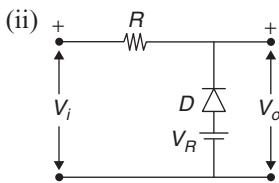
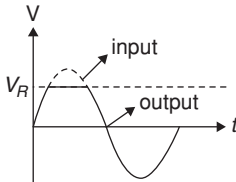
Clipping Circuits: Voltage Slicers

- (i) An electronic circuit which cuts the given input wave form
- (ii) The amount of clipping is decided by the supply voltage by which the circuit is driven

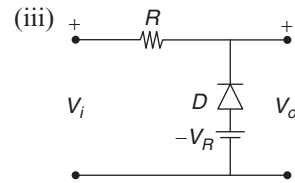
Considering ideal diode



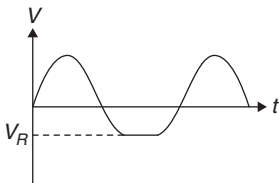
When $V_i > V_R$: Diode is forward biased $\Rightarrow V_o = V_R$
 When $V_i < V_R$: Diode is reverse biased $\Rightarrow V_o = V_i$



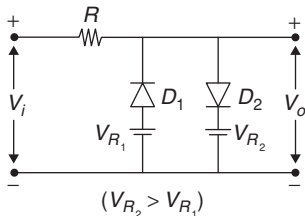
When $V_i > V_R$: Diode is reverse biased $\Rightarrow V_o = V_i$
 When $V_i < V_R$: Diode is forward biased $\Rightarrow V_o = V_R$



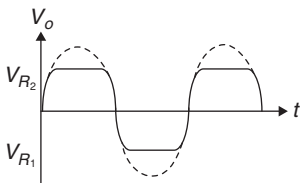
When $V_i > (-V_R)$: Diode is reverse biased $\Rightarrow V_o = V_i$
 When $V_i < (-V_R)$: Diode is forward biased $\Rightarrow V_o = -V_R$



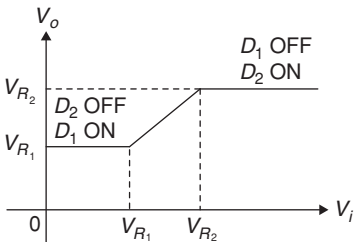
Clipping at two independent levels



Input	Diode state	V_o
$V_i \leq V_{R1}$	D_1 ON, D_2 OFF	V_{R1}
$V_{R1} \leq V_i < V_{R2}$	D_1 OFF, D_2 OFF	V_i
$V_i \geq V_{R2}$	D_1 OFF, D_2 ON	V_{R2}



Transfer Characteristics:



Clipping circuits are used to select for transmission, that part of a waveform which lies above or below same reference level.

Considering practical diode

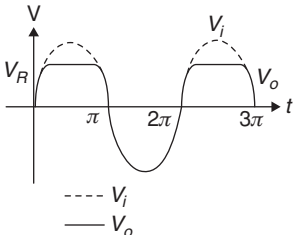
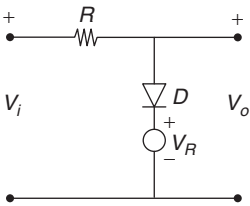


Figure 19 Diode clipping circuit

Figure 20 Input and output voltage waveforms

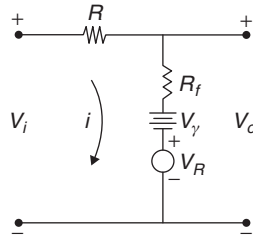


Figure 21 Model for circuit in forward bias $V_{in} > V_R + V_\gamma$

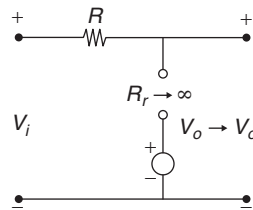


Figure 22 Model for circuit in reverse bias $V_{in} < V_R + V_\gamma$

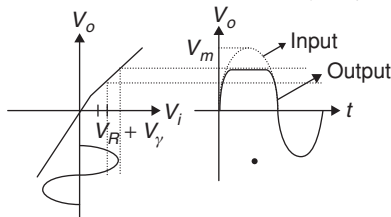
The diode will be ON during forward bias, as shown in Figure 21 by applying KVL

$$i = \frac{V_i - V_R - V_\gamma}{R_f + R}$$

$$V_o = iR_f + V_\gamma + V_R = \frac{R_f}{R_f + R} V_i + \frac{R}{R + R_f} (V_R + V_\gamma)$$

The translation from OFF to ON occurs when V_i equals to $V_\gamma + V_R$.

This transition indicates abrupt change in slope in the plot of V_o versus V_i , called transfer characteristic. The slope is unity, when diode is off, as $V_i = V_o$ (see Figure 22)



Transfer characteristic of clipping circuit

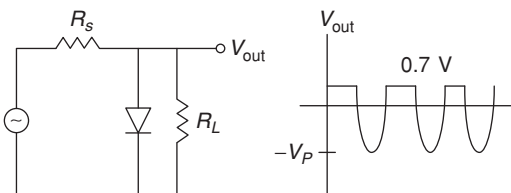


Figure 23 Positive clipper

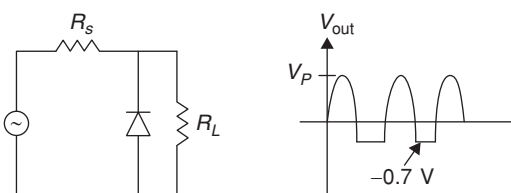


Figure 24 Negative clipper

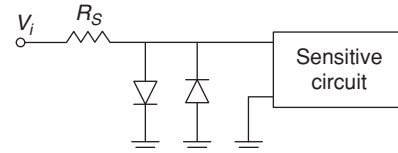


Figure 25 Limiter or diode clamp

If the input signal is so small (say 20 mV), none of the diode will be turned ON, so these small voltages will be not effected, but for higher voltages than ± 0.7 V one of the diode will be forward biased and the input to sensitive circuit will never cross ± 0.7 V.

A limiter on the input side of an op-amp will prevent excessive input voltage from being accidentally applied.

Biased clippers

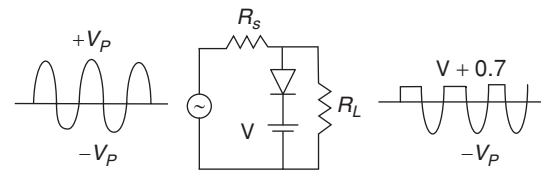


Figure 26 Positive clipper

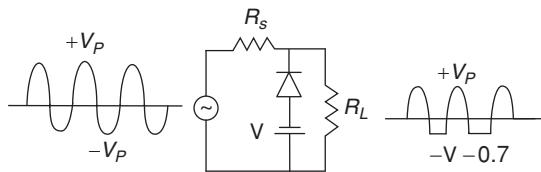


Figure 27 Negative clipper

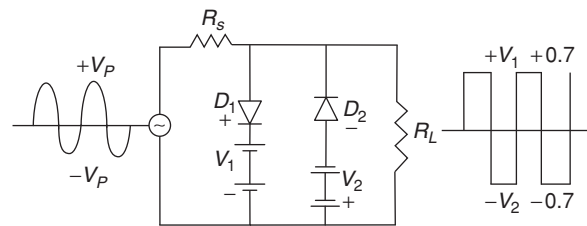


Figure 28 Biased positive-negative clipper

In the above combination clipper diode D_1 clips off positive parts above positive bias level, and diode D_2 clips off parts below the negative bias level. If input voltage is very large compared to the bias levels, the output signal is a square wave

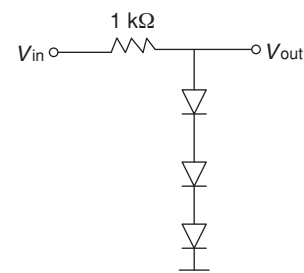


Figure 29 Clipper with three offset voltages

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Since each diode has an offset of around 0.7 V, three diodes produce a clipping level of +2.1 V, we can use the same circuit (see Figure 29) as a diode clamp to protect sensitive circuit, that cannot tolerate more than 2.1 V input

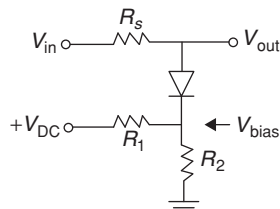


Figure 30 Voltage divider biases clipper

This is another way to bias a clipper without batteries. The voltage divider R_1 and R_2 to set the bias level, given by

$$V_{\text{bias}} = \frac{R_2}{R_1 + R_2} V_{\text{DC}}$$

In this case the output voltage is clipped or limited when the input is greater than $V_{\text{bias}} + 0.7 \text{ V}$

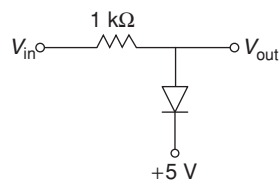


Figure 31 Diode clamp protects above 5.7 V

The circuit in Figure 31, it can be used to protect, sensitive circuits from excessive input voltages,

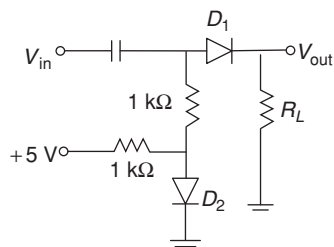


Figure 32 Circuit with zero off set

The circuit shown in Figure 32 is used to remove offset of limiting diode D_1 .

The diode D_2 is biased slightly into forward conduction, so it has 0.7 V across it, this 0.7 V is applied to D_1 and R_L via 1 kΩ. This means that diode D_1 is on the verge of conduction. Therefore when a signal carried in, diode D_1 conducts near 0 V.

Clamper Circuits

When a positive clamper has a sine wave input, it adds a positive dc voltage, to the sine wave,

Stiff clamper: $R_L C > 100 T$, T —time period.

The positive clamper shifts the AC reference level upto a DC level.

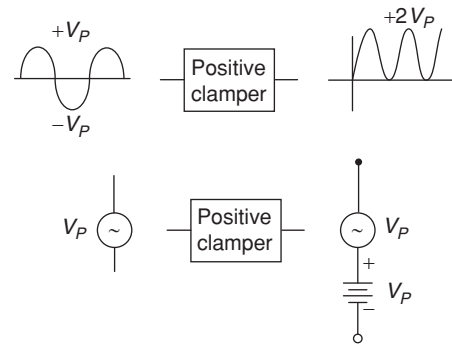


Figure 33 Practical clamper

The first quarter of the cycle charges the capacitor fully, then the capacitor retains almost all of its charge during subsequent cycles. The small charge that is lost between cycles, is replaced by diode conduction.

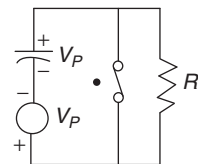


Figure 34 At positive peak

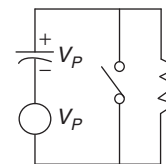


Figure 35 Beyond positive peak capacitor acts as battery

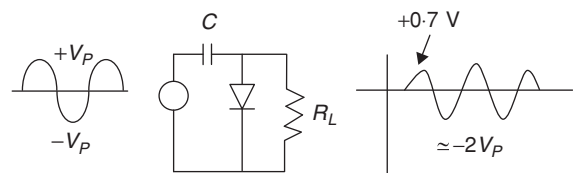


Figure 36 Negative clamper

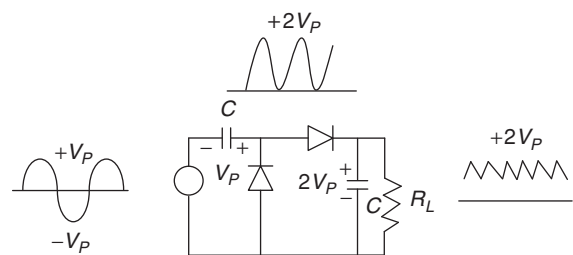


Figure 37 Peak to peak detector

A half wave rectifier with a capacitor input filter produces a DC output voltage approximately equal to the peak of input signal.

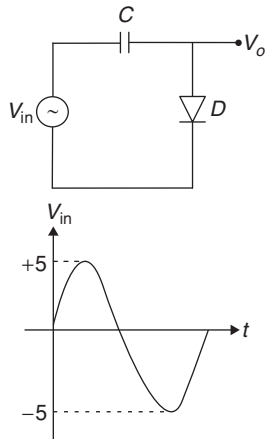
If we cascade a clamper and a peak detector, we will get a peak to peak detector.

The RC time constant should be much greater than the period of the signal (T) to get good clamping.

Steps to draw clamper output

- Find the voltage across the capacitor at input peak state.
- Replace the diode with open circuit, and draw the output waveform.

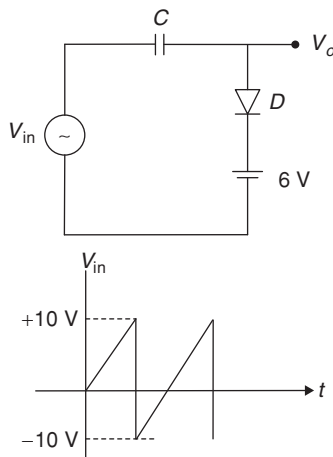
Example 4: Find the output of clamper circuit in the given figure



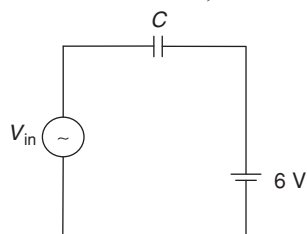
Solution: Under peak state $V_c = +5$ V KVL at input side gives $V_{in} - V_c - V_o = 0$

$$V_o = V_{in} - 5$$

Example 5: Find the output of clamper circuit in the given figure



Solution: At peak state condition, diode forward biased



$\therefore V_c$ (saturation) = 4 V

KVL at input gives, after replacing diode with short circuit

$$V_o = V_{in} - 4$$

VOLTAGE MULTIPLIERS

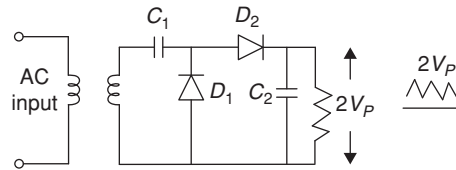


Figure 38 Voltage doubler with floating loads

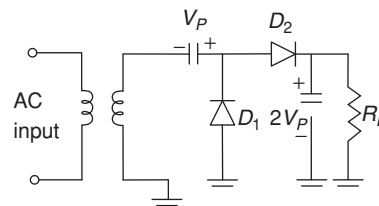


Figure 39 Voltage doubler with grounded loads

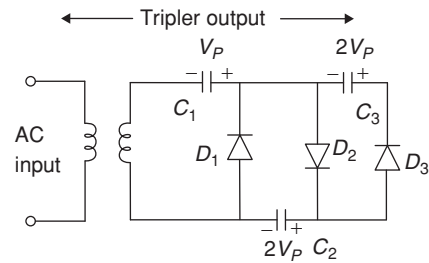


Figure 40 Voltage tripler with floating load

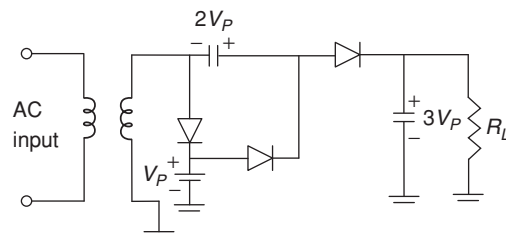


Figure 41 Voltage tripler with grounded load

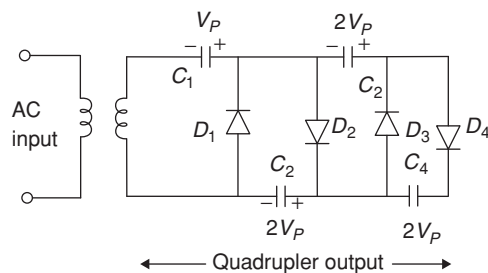


Figure 42 Voltage quadrupler with floating loads

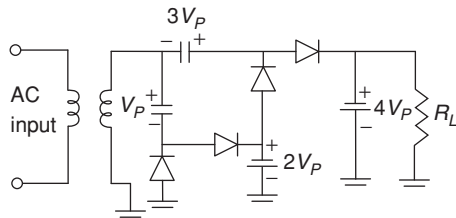


Figure 43 Voltage quadrupler with grounded load

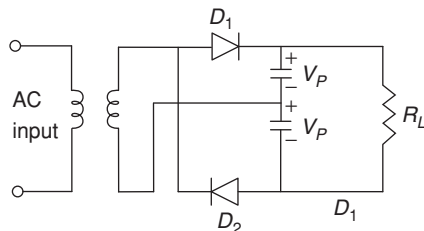


Figure 44 Voltage multiplier–full wave doubler

Voltage doubler is a redesign of the peak to peak detector, it uses rectifier diodes instead of small-signal diodes. It produces an output equal to the peak value of the rectified signal.

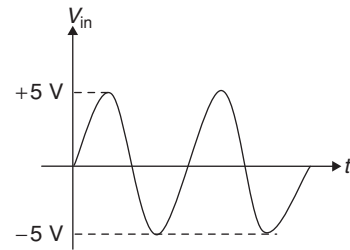
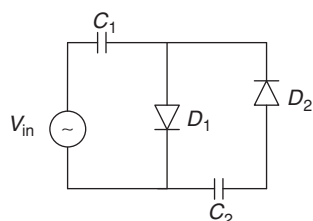
In voltage tripler, the first two sections act like a doubler, at peak of the negative half cycle, D_3 is forward biased. This charges C_2 to $2V_p$ with the polarity shown in figure 40. The tripler output appears across C_1 and C_3 .

Voltage quadrupler with four sections in cascade, the first three sections are a tripler, and the fourth makes the overall circuit quadrupler. The quadrupler output is across the series connections C_2 and C_4 .

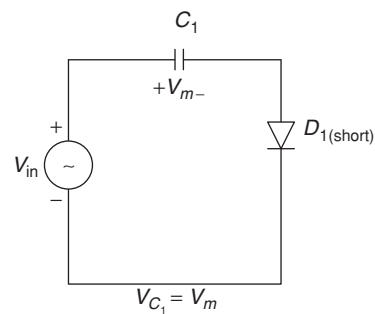
Figure 44 shows a full wave voltage doubler, on the positive half cycle of the source, the upper capacitor charges to the peak voltage with the polarity shown, on the peak next half cycle, lower capacitor charges to the voltage, with indicated polarity, final output voltage is approximately $2V_p$.

The voltage multipliers shown in figure 38–43 are half wave designs, i.e., the output ripple frequency is same as input frequency, but full wave voltage doubler, output ripple is double the input frequency. So its easy to filter the ripple and PIV is also V_p only.

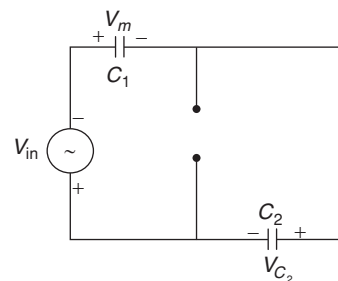
Voltage doubler analysis



During positive half cycle D_1 is ON and hence ' C_1 ' is charged to $+V_m$



During negative cycle:

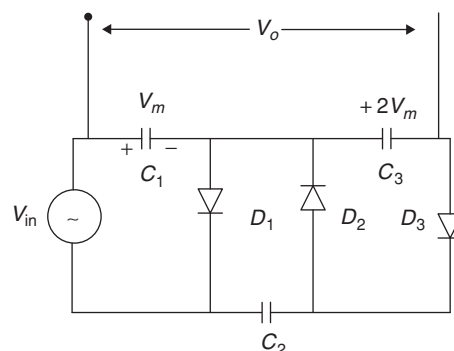


$$-V_{in} - V_m - V_{c_2} = 0$$

$$V_{c_2} = -V_{in} - V_m$$

$$V_{c_2} = -2V_m$$

Voltage tripler analysis



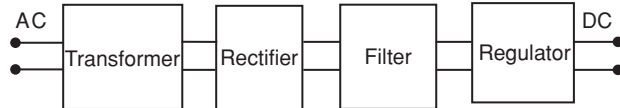
During first positive half cycle D_1 is ON. During next negative half cycle D_2 alone ON

$$\therefore V_o = V_{c1} + V_3 = 3V_m$$

During second positive half cycle D_1 and D_3 ON

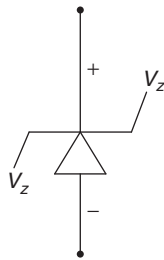
POWER SUPPLIES

Transformers are used for step-up or step down the level of input ac voltage.

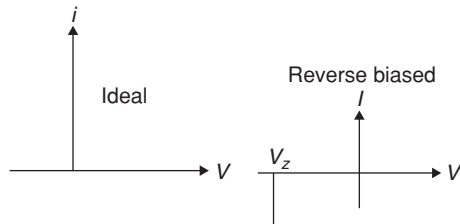


Voltage Regulators

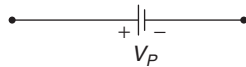
Zener diode can be used as a voltage regulator.



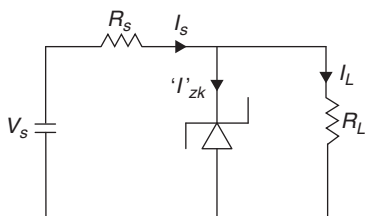
When forward biased



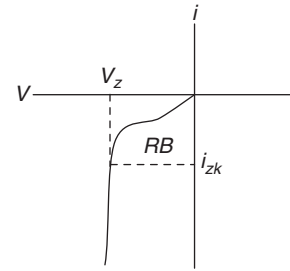
Zener reverse ON condition:



Zener voltage regulator



I - V Characteristics:



When source voltage varying:

$$I_s (\text{min}) = I_z (\text{min}) + I_L (\text{fix})$$

$$I_s (\text{max}) = I_z (\text{max}) + I_L (\text{fix})$$

When load is varying:

$$I_s (\text{fix}) = I_z (\text{min}) + I_z (\text{max})$$

$$I_s (\text{fix}) = I_z (\text{max}) + I_z (\text{min})$$

Zener diode withstand the current variations due to variations in source and load resistance when it is in reverse 'ON' condition and hence produces a constant output voltage across the Load.

Steps to determine the state of Zener Diode

- Replace the Zener diode with open circuit.
- Find the terminal voltage across the diode from 'n' to 'p' side let say V_t .
- If $V_t > V_z$ then Zener is reverse ON and diode is replaced with a voltage source of V_z .
- If $V_t < V_z$, then Zener is OFF and hence replace it with open circuit.

Example 6: Check the status of Zener diode when

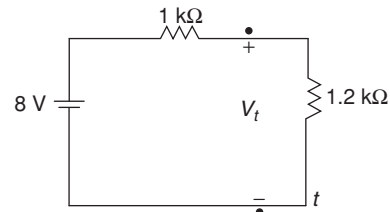
(i) $R_L = 1.2 \text{ k}\Omega$

(ii) $R_L = 3.6 \text{ k}\Omega$

[Given $V_z = 6 \text{ V}$ and $V_s = 8 \text{ V}$, $R_s = 1 \text{ k}\Omega$ determine the output voltage]

Solution: Case (1):

$$R_L = 1.2 \text{ k}\Omega$$



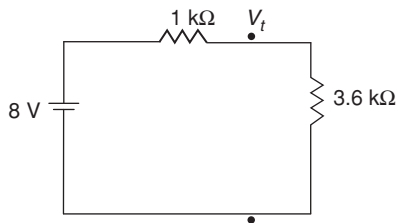
$$V_t = \frac{8(1.2)}{2.2} = 4.3 \text{ V}$$

$V_t < V_z$, hence Zener diode is in OFF condition.

$$\therefore V_o = 4.3 \text{ V}$$

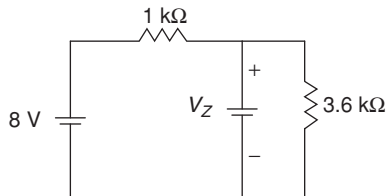
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Case (2): $R_L = 3.6 \text{ k}\Omega$



$$V_t = \frac{8(3.6)}{4.6} = 6.26087$$

$V_t < V_z$, hence Zener is in 'ON' condition.



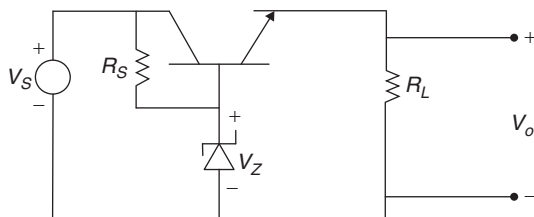
$$\therefore V_o = V_z = 6 \text{ V}$$

Note: The conventional direction of Zener voltage is considered to be opposite to the direction of ordinary PN junction diode, because PN junction is used in FB direction, and Zener diode is used in RB direction.

Characteristics of a ideal voltage regulator

- (i) It should maintain a constant output voltage irrespective of variations in input and the load.
- (ii) Load current should depend on R_L .

Voltage regulator using BJT



as ' V_s ' changes $\Rightarrow V_z$ constant

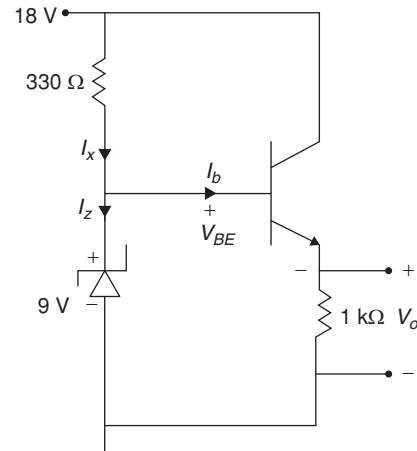
$\Rightarrow I_b$ is constant

$$I_E = (\beta + 1) I_b$$

Hence $I_E = \text{constant}$

$\therefore V_o = I_E R_L = \text{constant}$ irrespective of variations in the input circuit.

Example 7:



Find current I_z if $\beta = 99$ and $V_{BE} = 0.7 \text{ V}$

- (A) 0.0264 A
- (B) 0.352 A
- (C) 0.476 A
- (D) 0.0123 A

Solution: (A)

KVL at input side gives $-9 + 0.7 + V_L = 0$

$$\text{KCL} \Rightarrow I_x = I_b + I_z$$

$$I_z = I_x - I_b$$

$$I_x = \frac{18 - 9}{330 \Omega} = 0.02727 \text{ A}$$

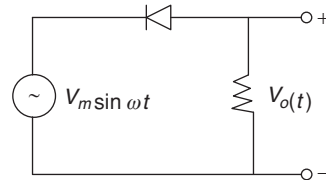
$$I_b = \frac{1}{100} \cdot \frac{V_L}{1 \text{ k}\Omega} = \frac{8.3}{100 \text{ k}\Omega} = 0.083 \text{ mA}$$

$$\therefore I_z = 0.0264 \text{ A}$$

Solved Examples

Directions for questions 1 to 8: Select the correct alternative from the given choices.

Example 1: The average value of $V_o(t)$ will be



- (A) 0
- (B) $\frac{-V_m}{\pi}$
- (C) $\frac{-V_m}{\sqrt{2}}$
- (D) $-V_m$

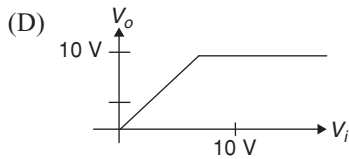
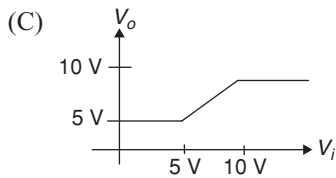
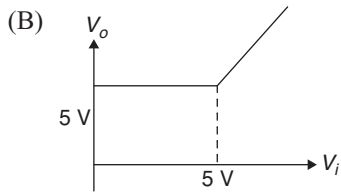
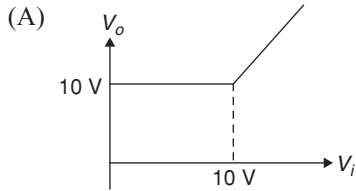
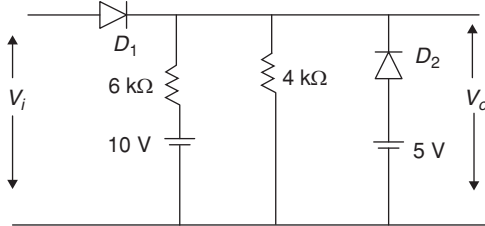
Solution: (B)

$$V_{av} = \frac{\int_{\pi}^{2\pi} V_m \sin \omega t d\omega t}{2\pi}$$

$$= \frac{V_m [-\cos \omega t]_{\pi}^{2\pi}}{2\pi} = \frac{-V_m}{\pi}$$

The diode will be ON for π to 2π .

Example 2: If D_1, D_2 diode are ideal, which of the following represents transfer characteristics of circuit:



Solution: (B)

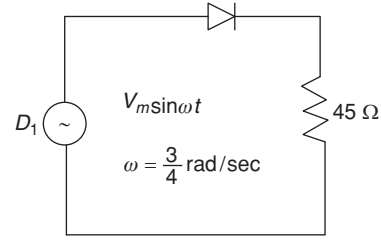
For $0 \leq V_i \leq 5$ V, D_2 is ON and $V_o = 5$ V

For $5 \leq V_i \leq 10$ V, D_2 is off and $V_o = V_i$

For $V_i > 10$ V, D_1 is ON, D_2 is OFF

$V_o = V_i$

Example 3: The forward resistance of the diode shown in circuit is 5Ω , and the other parameters are the same as those of an ideal diode. Then what is the DC component of the source current?



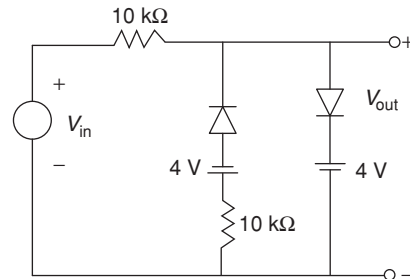
- (A) $\frac{-V_m}{50\pi}$ (B) $\frac{V_m}{45\pi\sqrt{2}}$
 (C) $\frac{V_m}{100\pi\sqrt{2}}$ (D) $\frac{2V_m}{45}$

Solution: (A)

$$I_{DC} = \frac{\int_0^\pi V_m \sin \omega t \cdot d\omega t}{2\pi \cdot R} = \frac{|V_m \cdot \cos \omega t|_0^\pi}{2\pi \cdot R} = \frac{V_m}{50\pi}$$

$$R = R_{f(\text{diode})} + 45 \Omega = 5 + 45 \Omega = 50 \Omega$$

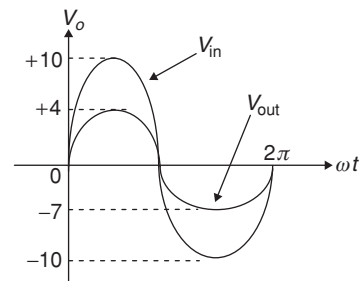
Example 4: A voltage signal $10 \sin \omega t$ is applied to the circuit with ideal diode, as shown. The maximum and minimum values of the output waveform V_{out} of the circuit are respectively



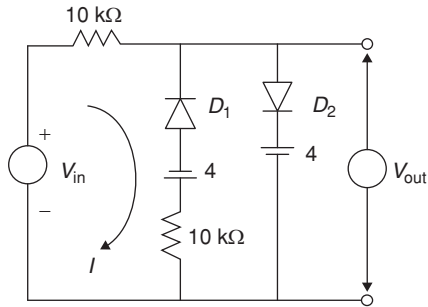
- (A) +10 V and -10 V (B) +4 V and -4 V
 (C) +7 V and -4 V (D) +4 V and -7 V

Solution: (D)

The voltage waveform at the output will be as shown below for +ve cycle



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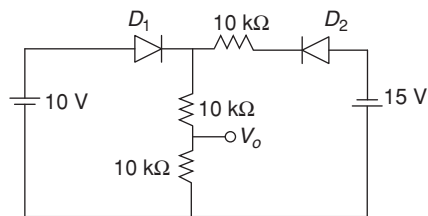
D_2 ON, D_1 OFF, $V_{out} = 4$ V,
for -ve cycle D_1 ON, D_2 OFF

$$I = \frac{V_{in} + 4}{20}$$

$$= \frac{-10 + 4}{20} = \frac{-3}{10} \text{ mA}$$

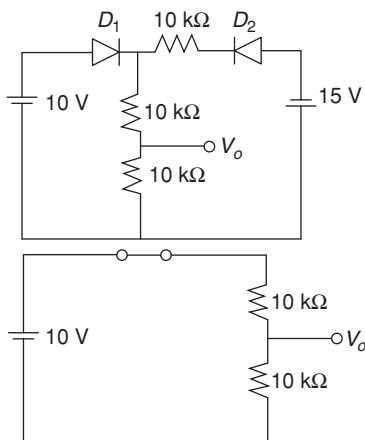
$$V_{out} = I \cdot R - 4 = -7 \text{ V}$$

Example 5: Assuming that the diode in the given circuit is ideal, the voltage V_o is



- (A) 4 V (B) 5 V
(C) 7.5 V (D) 12.1 V

Solution: (B)

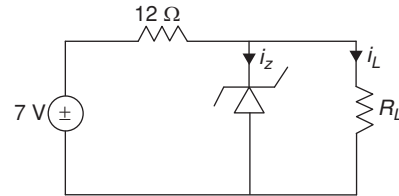


In this case the diode D_2 is always reverse biased

$$V_o = \frac{10K}{10K + 10K} \times 10 = 5 \text{ V}$$

Common Data for Questions 6 to 8:

Example 6:



In the voltage regulator circuit shown, the Zener diode current is to be limited to the range $5 \leq i_z \leq 100$ mA

$$V_z = 4 \text{ V}, R_z = 0 \Omega$$

The range of possible load current is

- (A) $5 \leq i_L \leq 130$ mA
(B) $25 \leq i_L \leq 250$ mA
(C) $10 \leq i_L \leq 110$ mA
(D) $150 \leq i_L \leq 245$ mA

Solution: (D)

$$\text{Current through } 12 \Omega \text{ resistor } i = \frac{7 - 4}{12} = 250 \text{ mA}$$

$i_L = i - i_z$, and i_z is in range of 5 to 100 mA

So i_L will be $150 \text{ mA} \leq i_L \leq 245 \text{ mA}$.

Example 7: Range of possible load resistance is

- (A) $60 \leq R_L \leq 375 \Omega$ (B) $20 \leq R_L \leq 60 \Omega$
(C) $40.1 \leq R_L \leq 92.1 \Omega$ (D) $16.3 \leq R_L \leq 26.6 \Omega$

Solution: (D)

$$i_L R_L = 4 \text{ V}, 150 \text{ mA} \leq i_L \leq 245 \text{ mA}$$

So R_L will be $16.3 \Omega \leq R_L \leq 26.67 \Omega$

Example 8: The power rating required for load resistance is

- (A) 576 mW (B) 480 mW
(C) 360 mW (D) 980 mW

Solution: (D)

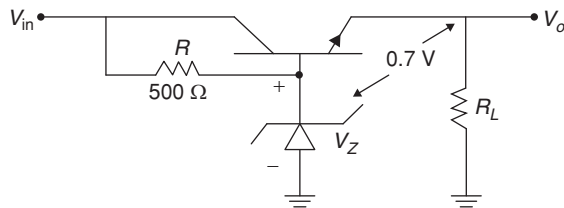
The power rating required for output resistance is $i_L = 245$ mA,
 $V_z = 4$ V, $i_L V_z = 0.98$ W

EXERCISES

Practice Problems 1

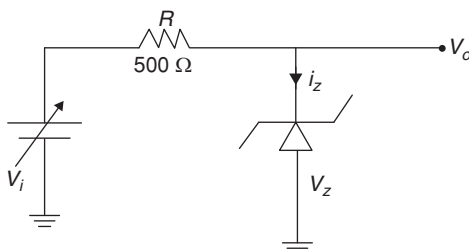
Directions for questions 1 to 28: Select the correct alternative from the given choices.

- A power supply having an output resistance $1.5\ \Omega$ supplies full load current of 500 mA to a $50\ \Omega$ load. What is the % voltage regulation of supply?
(A) 2% (B) 3%
(C) 6% (D) 1.5%
- What is the no-load output voltage of the supply in above problem?
(A) 25 V (B) 24.25 V
(C) 25.75 V (D) 25.25 V
- A transistor series voltage regulator is shown below. The input voltage V_{in} can vary from 18 V to 30 V. If $V_Z = 10\text{ V}$, $R_L = 1\text{ k}\Omega$, β -very high



The minimum collector to emitter voltage (V_{CE}) of the transistor is,

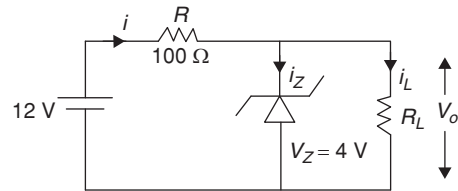
- (A) 8.7 V (B) 20.7 V
(C) 7.3 V (D) 19.3 V
- The minimum power dissipated in the transistor is
(A) 0.192 W (B) 2.1 W
(C) 80.9 mW (D) None
- The max current supplied by V_{in} is
(A) 40 mA (B) 9.3 mA
(C) 24.5 mA (D) 49.3 mA
- A FWR is operated from 230 V, 50 Hz line has a capacitor filter across its output. Calculate the minimum value of capacitance required if the load is $1\text{ k}\Omega$ and the ripple must not exceed 5%
(A) $57.8\ \mu\text{F}$ (B) $10\ \mu\text{F}$
(C) $28.6\ \mu\text{F}$ (D) $5.7\ \mu\text{F}$
- A Zener diode voltage regulator is given below with following specifications $I_{Z_{\min}} = 4\text{ mA}$, $I_{Z_{\max}} = 24\text{ mA}$, $V_Z = 4.8\text{ V}$, and $R_Z = 10\ \Omega$



Calculate minimum, and maximum input voltage that can be regulated by Zener diode

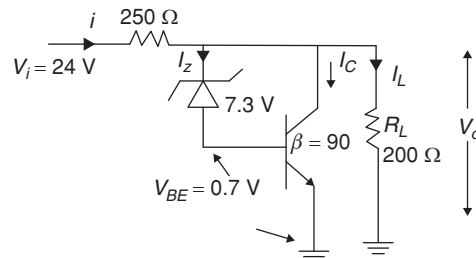
- (A) 9.8 V and 25.04 V (B) 6.84 V and 25.04 V
(C) 9.8 V and 17.04 V (D) 6.84 V and 17.04 V

- The line regulation is
(A) 1.3% (B) 2.5%
(C) 1.96% (D) 0%
- In the circuit shown below, the knee current of ideal Zener diode is 8 mA . To maintain 4 V across R_L , the minimum value of R_L and minimum power rating of Zener diode in mW respectively are



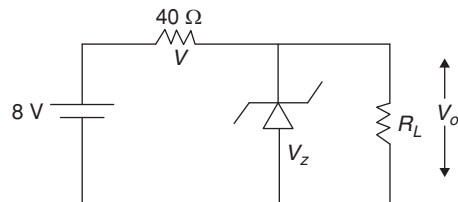
- (A) $55\ \Omega$ and 320 mW (B) $55\ \Omega$ and 288 mW
(C) $50\ \Omega$ and 320 mW (D) $50\ \Omega$ and 288 mW

- A transistor shunt voltage regulator is given below



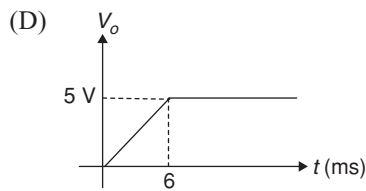
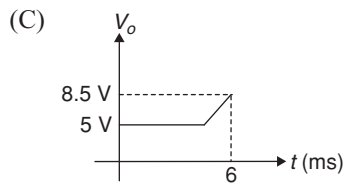
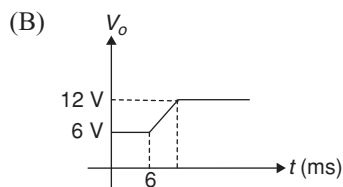
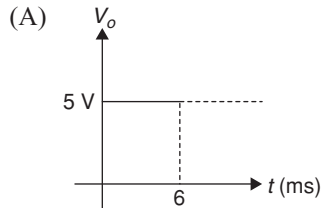
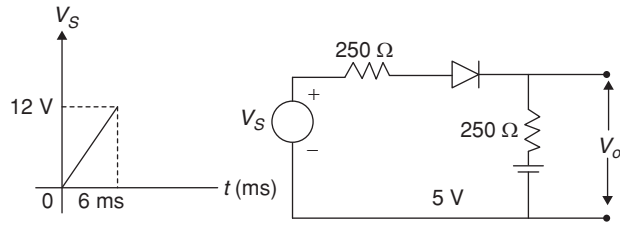
The collector current i_C is

- (A) 10 mA (B) 24 mA
(C) 64 mA (D) 40 mA
- The power dissipation in Zener diode is
(A) 1.89 mW (B) 2.5 W
(C) 3.1 mW (D) None of these
- A Zener diode in the circuit shown below, has a knee current of 4 mA and power dissipation of 200 mW . What are the minimum and maximum load currents that can be drawn safely from the circuit, keeping the output $V_o = 5\text{ V}$.

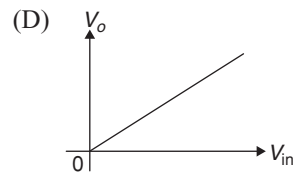
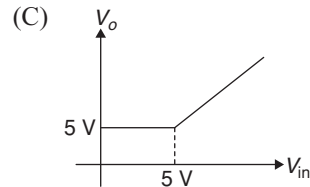
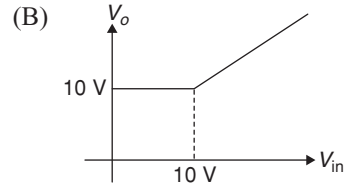
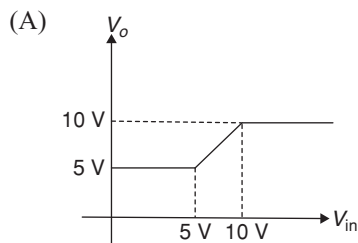
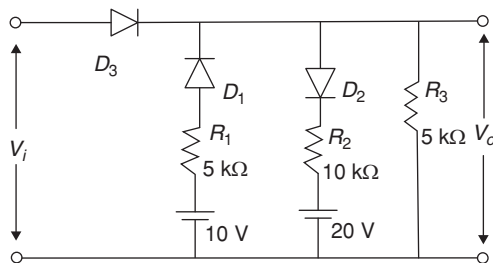


- (A) 0 mA and 200 mA (B) 4 mA and 11 mA
(C) 35 mA and 71 mA (D) 35 mA and 200 mA

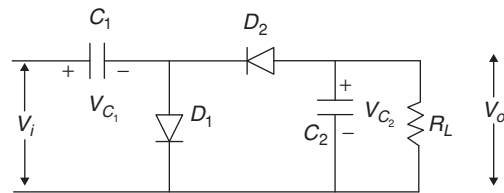
- Sketch the output V_o of the circuit given for $0 \leq t \leq 6\text{ ms}$, assume the diode is ideal



14. Draw the transfer characteristic (V_o vs V_i) for the circuit given below.



15. A voltage doubler is given below.

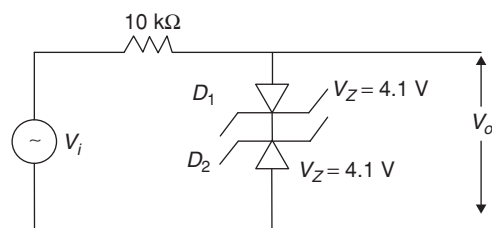
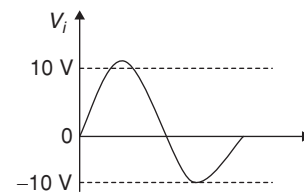


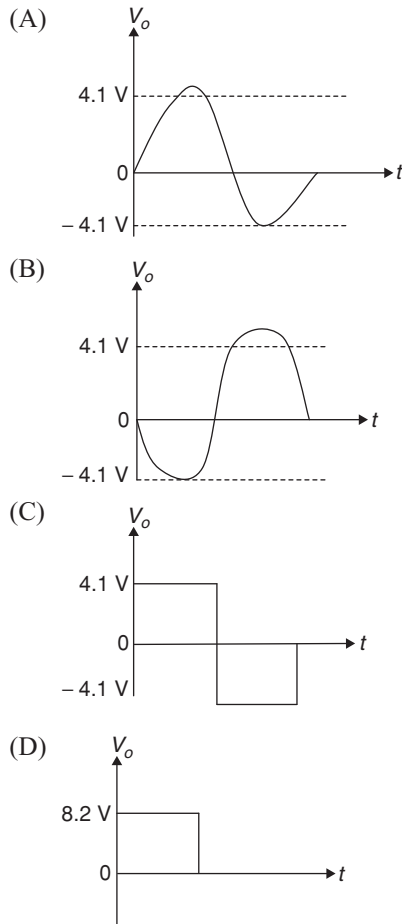
Where $V_i = 6 \sin \omega t$ V

The voltage across C_1 and C_2 are

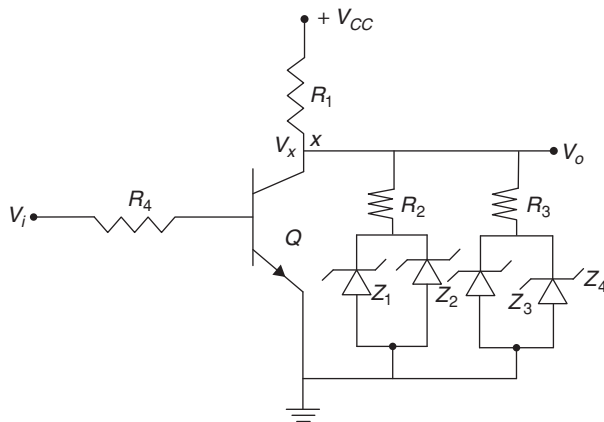
- (A) 6 V and 6 V (B) 6 V and -12 V
(C) 6 V and 12 V (D) -6 V and -12 V
16. The PIV of D_1 and D_2 are
(A) 6 V and 6 V (B) 6 V and 12 V
(C) 12 V and 12 V (D) 12 V and 6 V

17. Draw the output V_o of the figures given.

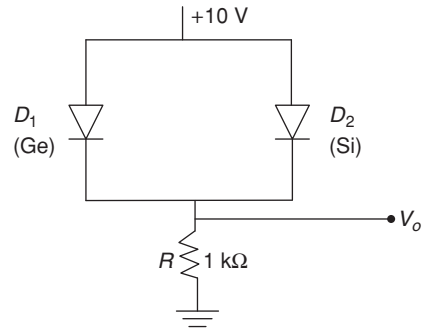




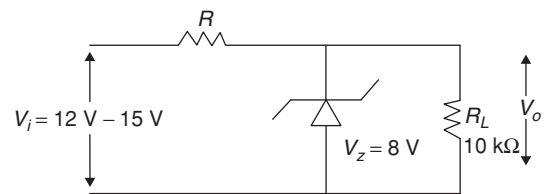
18. In the circuit given below, assume that $V_{CC} = 12$ V, Z_1 , Z_2 , Z_3 and Z_4 are identical Zener diodes with break down voltage of 4 V. $R_1 = R_4 = 4$ k Ω and $R_2 = R_3 = 8$ k Ω . Calculate V_o when Q is OFF.



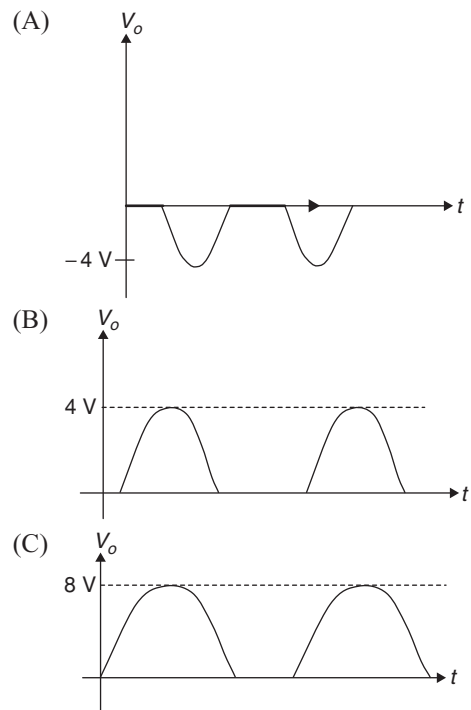
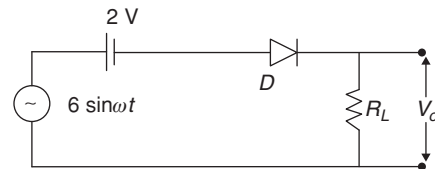
- (A) 7.3 V (B) 8 V
(C) 10 V (D) 8.5 V
19. In the given circuit, two diodes made up of Ge (cut in voltage = 0.3 V) and Si (cut in voltage = 0.7 V) are used. What is the value of V_o .

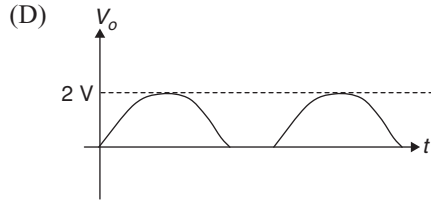


- (A) 10 V (B) 9 V
(C) 9.7 V (D) 9.3 V
20. What is the minimum value of R to maintain $V_o = 8$ V constant and I_z is negligible.

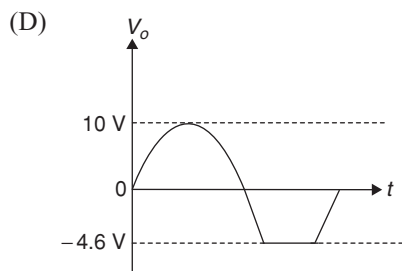
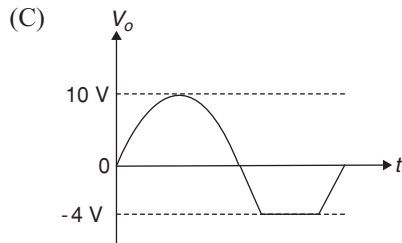
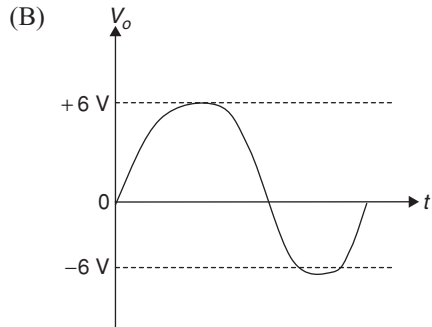
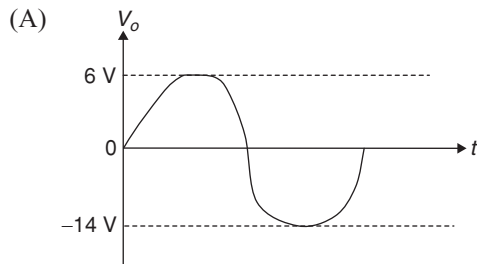
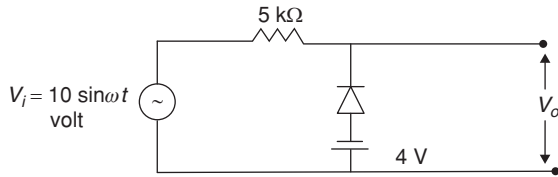


- (A) $R \leq 5$ k Ω (B) $R > 8.75$ k Ω
(C) 5 k $\Omega < R < 8.75$ k Ω (D) None of these
21. Draw the output V_o of the figure given below (assume diode is ideal)

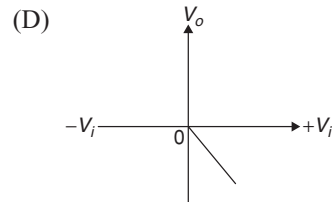
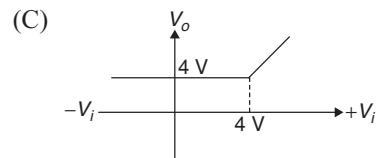
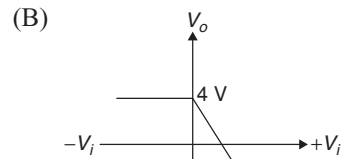
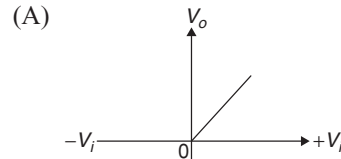
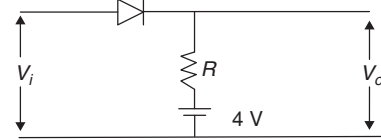




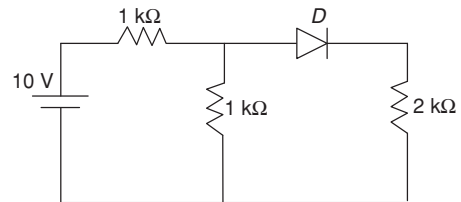
22. Draw the output V_o assume diode FB voltage drop is 0.6 V.



23. Draw the transfer characteristic of the figure given below (assume diode is ideal)

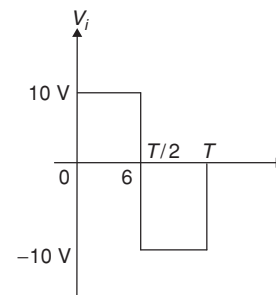


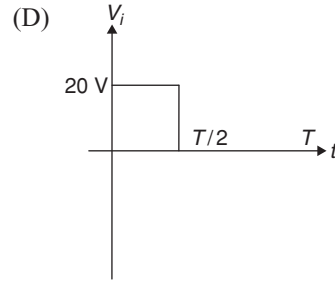
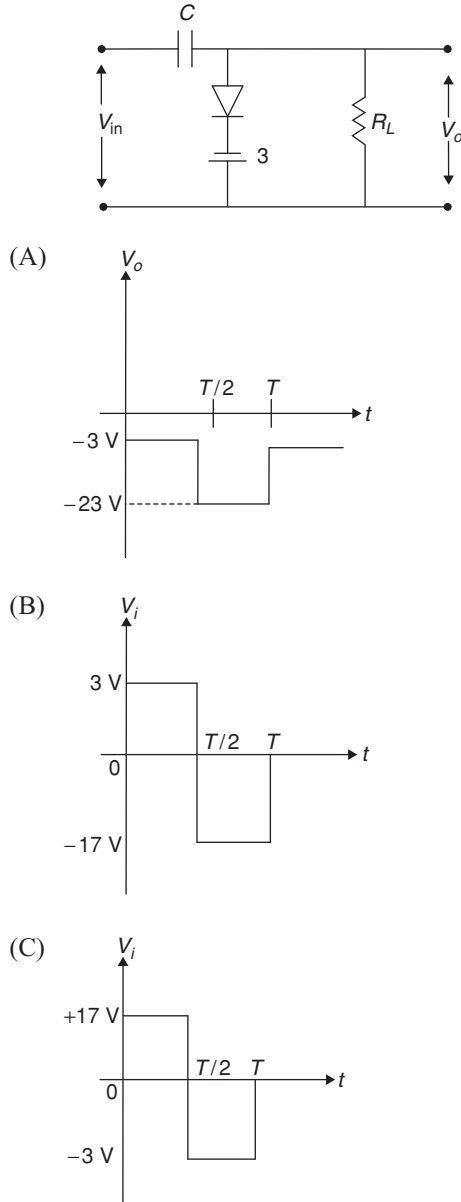
24. Calculate the voltage drop across 2 kΩ of the figure (assume the diode is ideal)



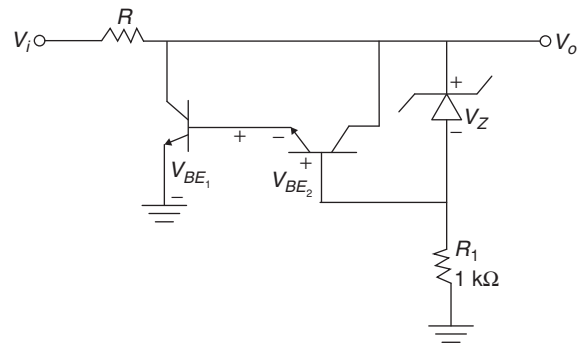
- (A) 10 V (B) 2 V
(C) 4 V (D) 0 V

25. Sketch the output wave form for the circuit given.





26. A HWR uses a transformer of turn ratio 2:1 and a load resistance of $500\ \Omega$. If the rms primary voltage is 240 V. The DC output voltage is
 (A) 54 V (B) 38 V
 (C) 76 V (D) None of these
27. The PIV of diode is
 (A) 120 V (B) 240 V
 (C) 360 V (D) 170 V
28. Find the output voltage of a shunt regulator given below with following specifications.
 $V_{BE_1} = V_{BE_2} = 0.6\text{ V}$ and $V_Z = 10\text{ V}$



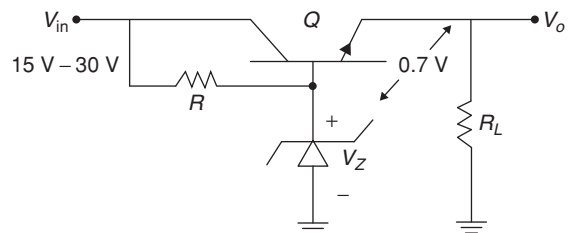
- (A) 10.6 V (B) 8.8 V
 (C) 10 V (D) 11.2 V

Practice Problems 2

Directions for questions 1 to 26: Select the correct alternative from the given choices.

- The DC output voltage is 45 V at full load and 47 V at no-load. The % regulation factor is
 (A) 2.5% (B) 1%
 (C) 4.25% (D) 4.44%
- In a FWR, the rms output is 10 V. What is its DC output voltage.
 (A) 10 V (B) 9 V
 (C) 5 V (D) 6 V

3. A transistor series voltage regulator is given below.



- What break down voltage V_Z should the Zener diode have if the load voltage is to be maintained at 12 V?
 (A) 11.3 V (B) 12.7 V
 (C) 12 V (D) None of these

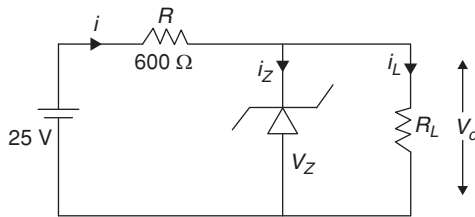
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4. If the Zener diode must conduct 12 mA to remain in the breakdown region, what minimum value should R have (in above problem)?

(A) 500 Ω (B) 1.4 k Ω
(C) 2 k Ω (D) 192 Ω

5. A Zener diode voltage regulator is given below with following specifications.

$$V_Z = 4.1 \text{ V}, I_{ZK} = 3 \text{ mA}, I_{Z\max} = 28 \text{ mA and } r_z = 0$$



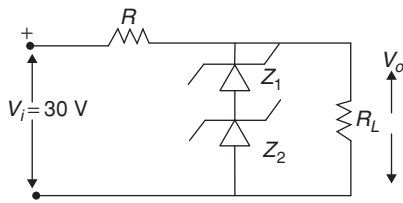
Calculate minimum and maximum load currents for which Zener diode will maintain regulation.

(A) 3 mA and 31.83 mA (B) 6.83 mA and 31.83 mA
(C) 6.83 mA and 28 mA (D) 3 mA and 28 mA

6. For above problem calculate the minimum value of R_L used

(A) 128 Ω (B) 85 Ω
(C) 600 Ω (D) 117 Ω

7. The circuit given below uses two Zener diodes, each is rated at 12 V, 100 mA and assume that load current is negligible.



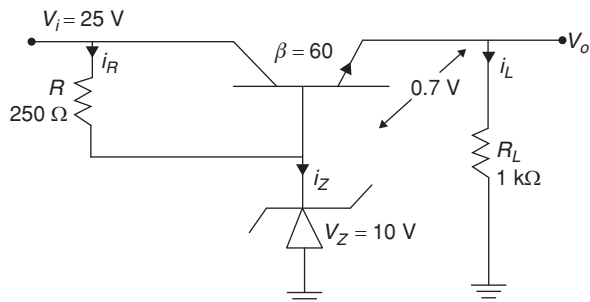
The regulated output V_o is

(A) 24 V (B) 12 V
(C) 6 V (D) 0 V

8. For above problem the value of series resistance R is

(A) 180 Ω (B) 15 Ω
(C) 60 Ω (D) None of these

9. A transistor series voltage regulator is given below



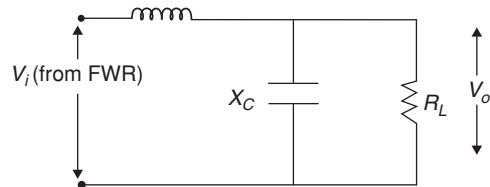
The output voltage V_o is

(A) 9.3 V (B) 10.7 V
(C) 10 V (D) 0.7 V

10. For above problem Zener current i_z is

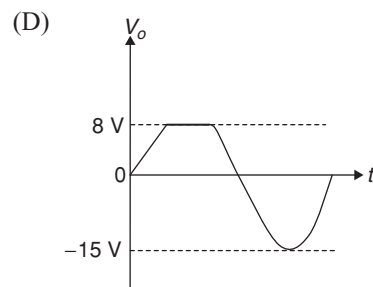
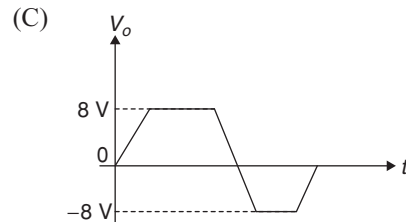
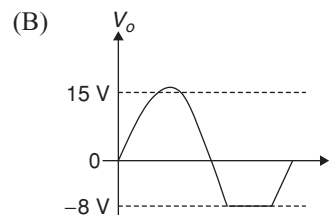
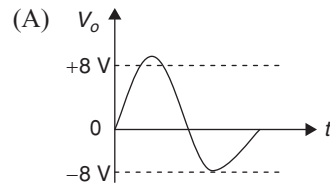
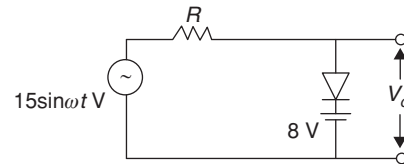
(A) 60 mA (B) 0.15 mA
(C) 59.84 mA (D) 10 mA

11. Calculate the ripple factor (γ) of L-section filter given below with $X_C = 10 \Omega$, $X_L = 100 \Omega$ and $R_L = 1 \text{ k}\Omega$.

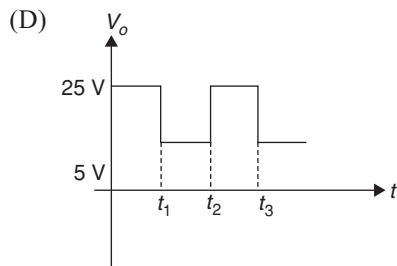
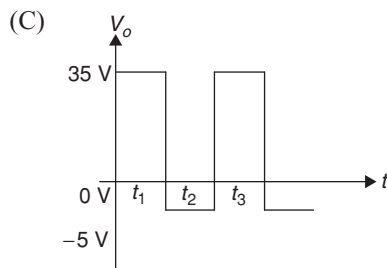
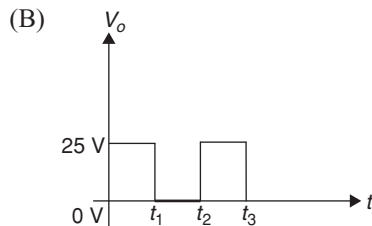
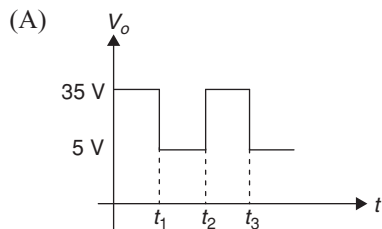
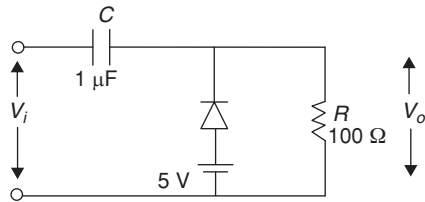
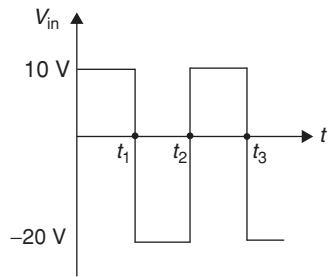


(A) 0.14 (B) 0.047
(C) 0.482 (D) 0.52

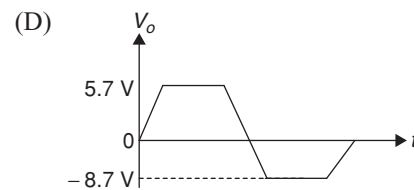
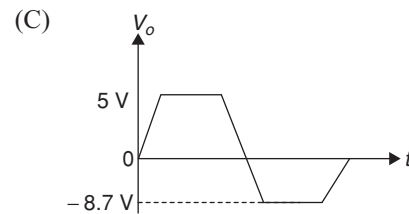
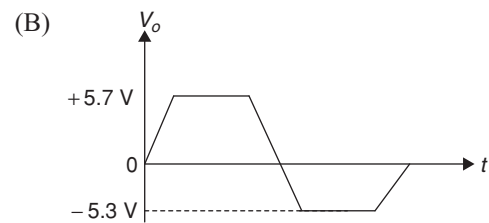
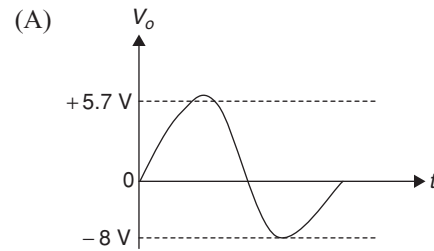
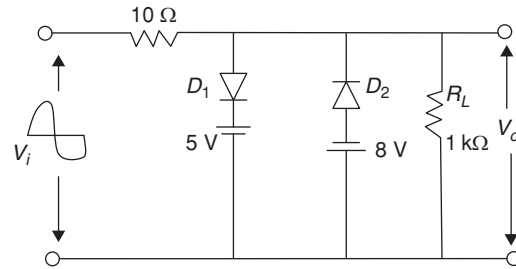
12. For the circuits given assume the diode is ideal sketch the output V_o .



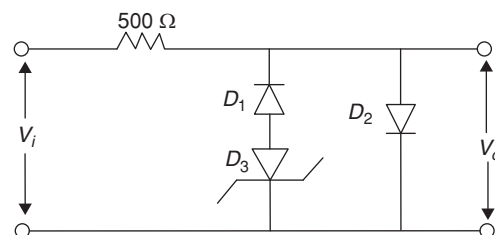
13. A DC restorer is shown below. Sketch the output V_o .



14. Draw the output V_o of the figure given. Assume forward voltage drop of each diode is 0.7 V.

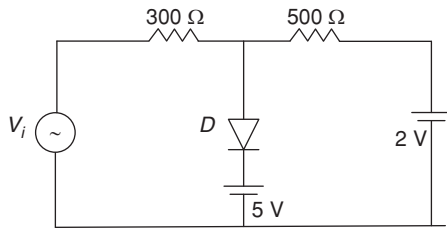


15. In the following limiter circuit, an input voltage $V_i = 12 \sin 100\pi t$ V is applied. Assume that the diode forward voltage drop is 0.6 V and Zener breakdown voltage is 4.2 V. What is the minimum and maximum value of output voltage?



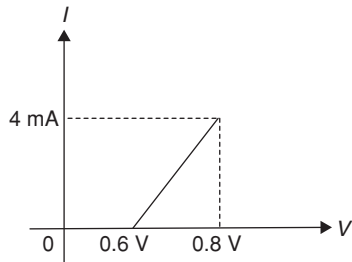
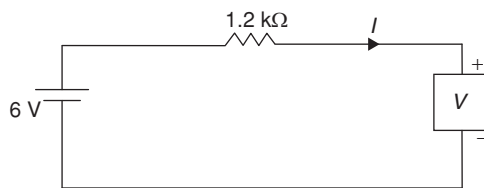
- (A) -0.6 V and 4.8 V (B) -4.8 V and 0.6 V
(C) 0.6 V and 4.2 V (D) -4.2 V and -0.6 V

16. Find input V_i for the diode to be FB



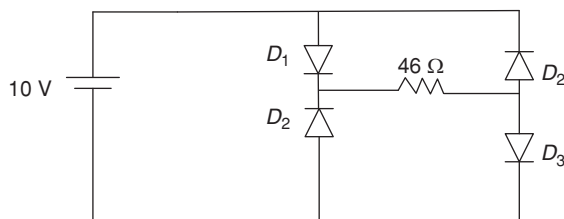
- (A) 7 V (B) 6.8 V
(C) 3 V (D) 5 V

17. Find current I for the given characteristic



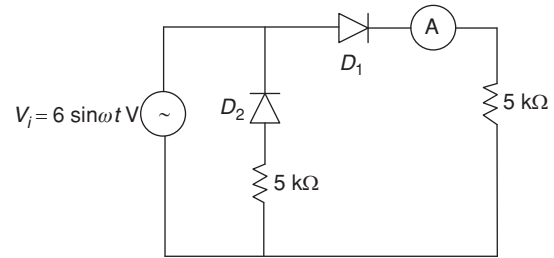
- (A) 4.32 mA (B) 5 mA
(C) 4 mA (D) 0

18. If the cut-in voltage and forward resistance of each diode are 0.6 V and $2\ \Omega$ respectively. The current passing through $46\ \Omega$ is



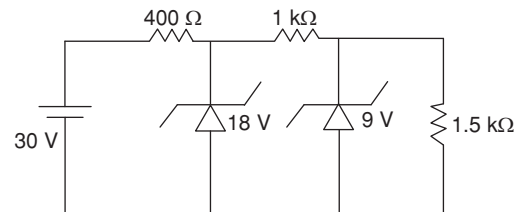
- (A) 0.176 A (B) 0.16 A
(C) 0 A (D) 0.2 A

19. In the circuit shown, assume that diodes are ideal an ammeter is rms value indicating meter with zero internal resistance. The ammeter reading is



- (A) 0.3 mA (B) 1.2 mA
(C) 0.6 mA (D) $\frac{1.2}{\pi}$ mA

20. What is the output voltage across $1.5\ \text{k}\Omega$ load in the circuit given below.



- (A) 18 V (B) 10.8 V
(C) 9 V (D) 5.4 V

21. An AC supply of 200 V, 50 Hz is applied to bridge rectifier through a transformer turn ratio 4:1. The diode forward resistance is $200\ \Omega$ and load $R_L = 1\ \text{k}\Omega$. What is the DC output current?

- (A) 31.8 mA (B) 26.54 mA
(C) 106 mA (D) None of these

22. What is the peak inverse voltage of diode?

- (A) 50 V (B) 100 V
(C) 200 V (D) 400 V

23. Output ripple frequency is

- (A) 100 Hz (B) 50 Hz
(C) 25 Hz (D) 0 Hz

24. A power supply is delivering 100 W to a load of $10\ \text{k}\Omega$. What is the AC (ripple) voltage across the load if the ripple factor is 0.1%.

- (A) 100 V (B) 10 V
(C) 1 V (D) 0.1 V

25. A full wave rectifier uses a centre tapped transformer. The AC voltage from its centre tap to either end is $20\sin 314t$ V. The load resistance of the circuit is $80\ \Omega$ and diode resistance is $20\ \Omega$. What is rms value of output current (I_{rms})?

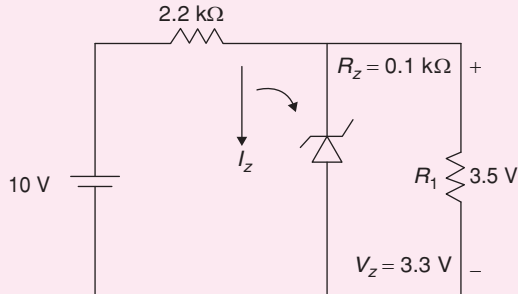
- (A) 0.2 A (B) 2 mA
(C) 20 mA (D) 0.14 A

26. Rectifier efficiency is

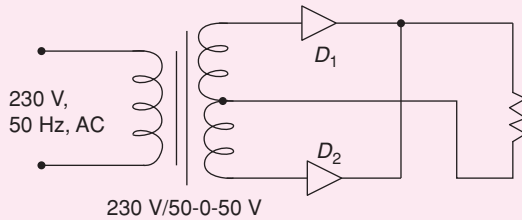
- (A) 81.2% (B) 64.96%
(C) 58.7% (D) 40.6%

PREVIOUS YEARS' QUESTIONS

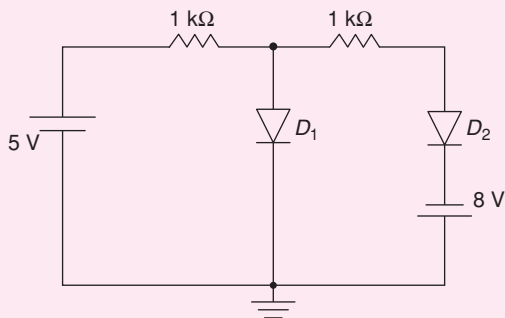
1. The current through the Zener diode in the figure is [2004]



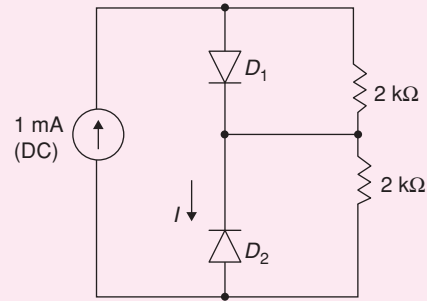
- (A) 33 mA (B) 3.3 mA
(C) 2 mA (D) 0 mA
2. The circuit in figure shows a full wave rectifier. The input voltage is 230 V (rms) single-phase AC. The peak reverse voltage across the diodes D_1 and D_2 is [2004]



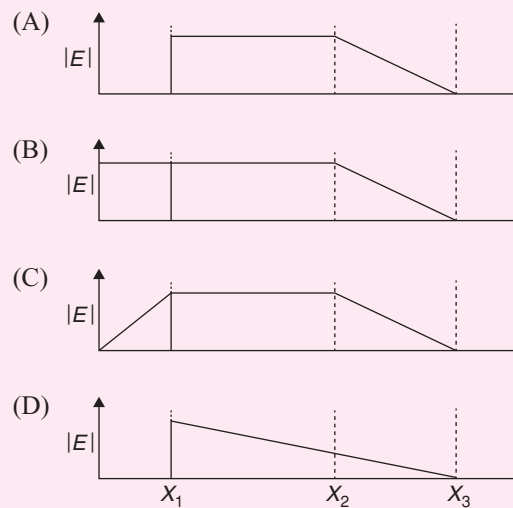
- (A) $100\sqrt{2}$ V (B) 100 V
(C) $50\sqrt{2}$ V (D) 50 V
3. Assuming that the diodes are ideal in figure, the current in D_1 is [2004]



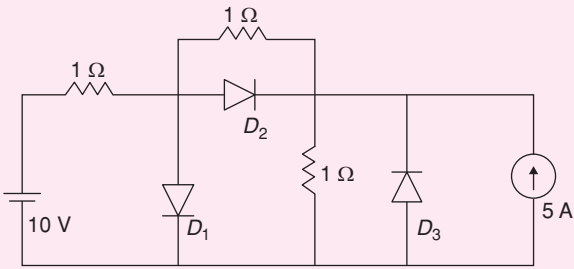
- (A) 8 mA (B) 5 mA
(C) 0 mA (D) -3 mA
4. Assume that D_1 and D_2 in the figure are ideal diodes. The value of current I is: [2005]



- (A) 0 mA (B) 0.5 mA
(C) 1 mA (D) 2 mA
5. A three-phase diode bridge rectifier is fed from a 400 V rms, 50 Hz, three-phase AC source. If the load is purely resistive, the peak instantaneous output voltage is equal to [2005]
- (A) 400 V (B) $400\sqrt{2}$ V
(C) $400\sqrt{\frac{2}{3}}$ V (D) $\frac{400}{\sqrt{3}}$ V
6. The charge distribution in a metal-dielectric-semiconductor specimen is shown in the figure. The negative charge density decreases linearly in the semiconductor as shown. The electric field distribution is as shown in [2005]

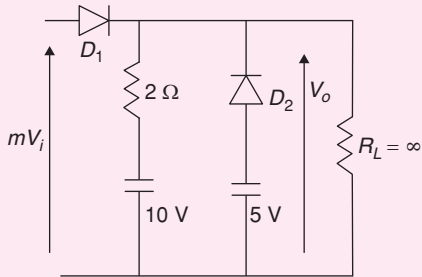


7. What are the states of the three ideal diodes of the circuit shown in figure? [2006]

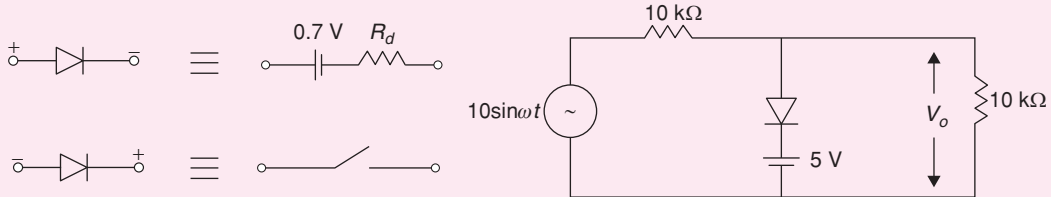


- (A) D_1 ON, D_2 OFF and D_3 OFF
 (B) D_1 OFF, D_2 ON and D_3 OFF
 (C) D_1 ON, D_2 OFF and D_3 ON
 (D) D_1 OFF, D_2 ON and D_3 ON

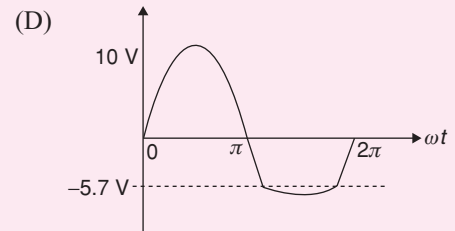
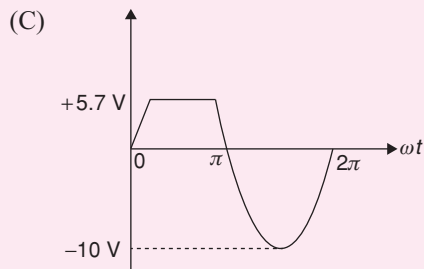
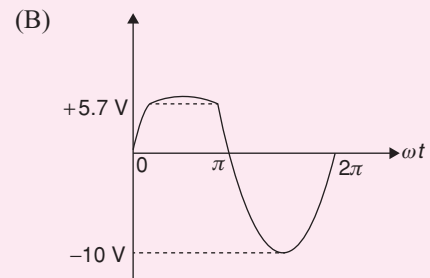
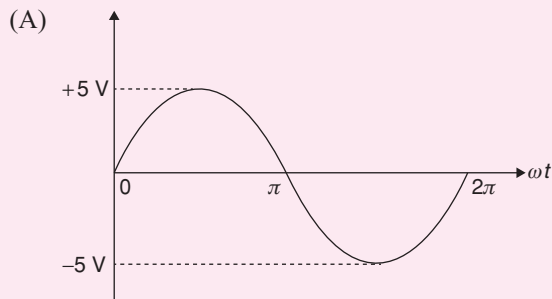
8. Assuming the diodes D_1 and D_2 of the circuit shown in the figure to be ideal ones, the transfer characteristics of the circuit will be [2006]



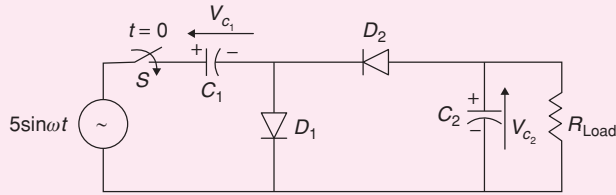
9. The equivalent circuits of a diode, during forward biased and reverse biased conditions, are shown in the figure.



If such a diode is used in clipper circuit of figure given above, the output voltage (V_o) of the circuit will be [2008]

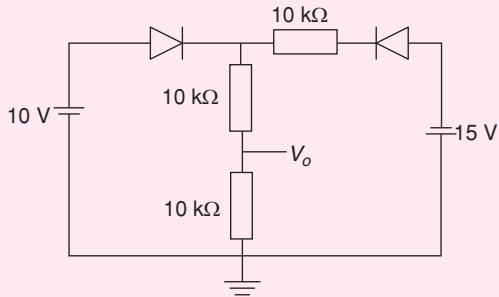


10. In the voltage doubler circuit shown in the figure, the switch 'S' is closed at $t = 0$. Assuming diodes D_1 and D_2 to be ideal, load resistance to be infinite and initial capacitor voltages to be zero, the steady state voltage across capacitors C_1 and C_2 will be [2008]



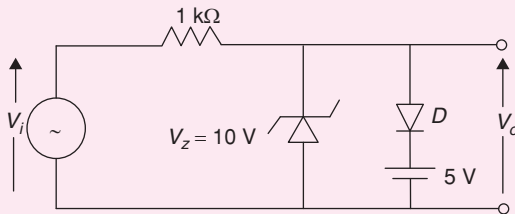
- (A) $V_{c1} = 10 \text{ V}$, $V_{c2} = 5 \text{ V}$ (B) $V_{c1} = 10 \text{ V}$, $V_{c2} = -5 \text{ V}$
 (C) $V_{c1} = 5 \text{ V}$, $V_{c2} = 10 \text{ V}$ (D) $V_{c1} = 5 \text{ V}$, $V_{c2} = -10 \text{ V}$

11. Assuming that the diodes in the given circuit are ideal, the voltage V_o is [2010]

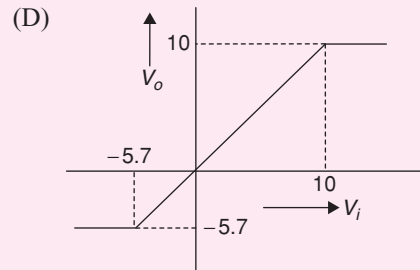
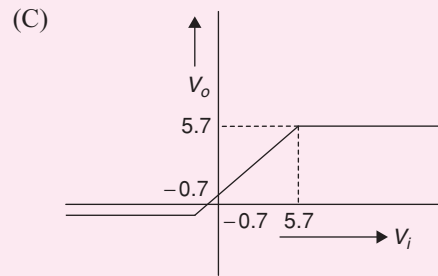
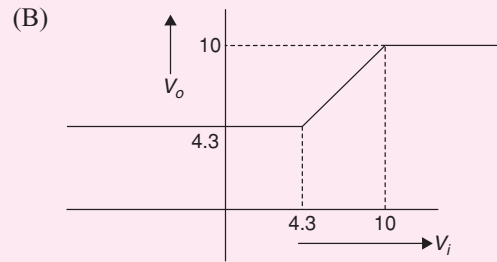
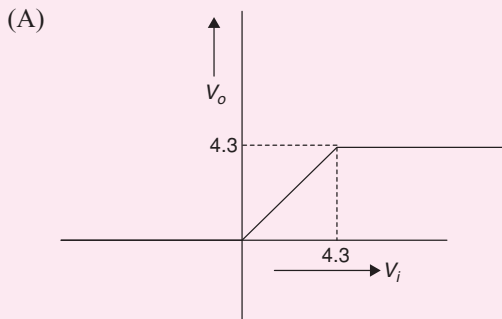


- (A) 4 V (B) 5 V
 (C) 7.5 V (D) 12.12 V

12. A clipper circuit is shown below.



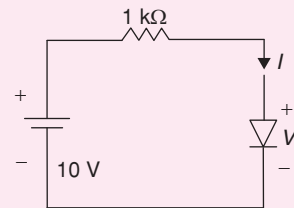
Assuming forward voltage drops of the diodes to be 0.7 V, the input-output transfer characteristic of the circuit is. [2011]



13. The I-V characteristics of the diode in the circuit given below are [2012]

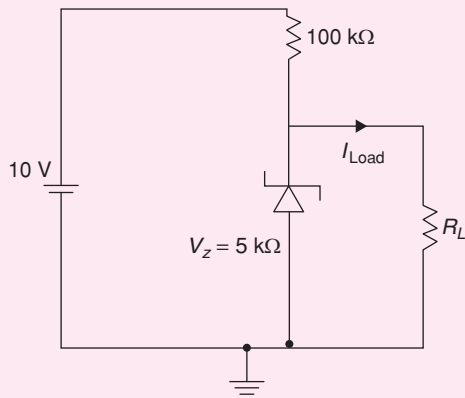
$$I = \begin{cases} \frac{V - 0.7}{500} \text{ A}, & V > 0.7 \text{ V} \\ 0 \text{ A}, & V < 0.7 \text{ V} \end{cases}$$

The current in the circuit is



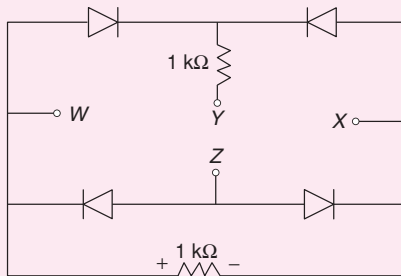
- (A) 10 mA (B) 9.3 mA
 (C) 6.67 mA (D) 6.2 mA

14. In the circuit shown below, the knee current of the ideal Zener diode is 10 mA. To maintain 5 V across R_L , the minimum value of R_L in Ω and the minimum power rating of the Zener diode in mW respectively are [2013]



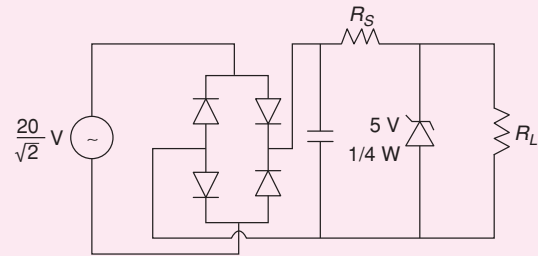
- (A) 125 and 125 (B) 125 and 250
(C) 250 and 125 (D) 250 and 250

15. A voltage $1000\sin\omega t$ V is applied across YZ . Assuming ideal diodes, the voltage measured across WX in V is [2013]

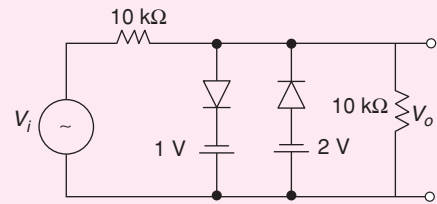


- (A) $\sin\omega t$ (B) $(\sin\omega t + |\sin\omega t|)/2$
(C) $(\sin\omega t - |\sin\omega t|)/2$ (D) 0 for all t

16. A sinusoidal AC source in the figure has an rms value of $\frac{20}{\sqrt{2}}$ V. Considering all possible values of R_L , the minimum value of R_s in Ω to avoid burnout of the Zener diode is _____. [2014]



17. Assuming the diodes to be ideal in the figure, for the output to be clipped, the input voltage V_i must be outside the range [2014]



- (A) -1 V to -2 V (B) -2 V to -4 V
(C) +1 V to -2 V (D) +2 V to -4 V

ANSWER KEYS

EXERCISES

Practice Problems 1

- | | | | | | | | | | |
|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|
| 1. B | 2. C | 3. A | 4. A | 5. D | 6. A | 7. D | 8. C | 9. A | 10. B |
| 11. A | 12. C | 13. C | 14. C | 15. B | 16. C | 17. C | 18. B | 19. C | 20. A |
| 21. B | 22. D | 23. C | 24. C | 25. A | 26. A | 27. D | 28. D | | |

Practice Problems 2

- | | | | | | | | | | |
|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|
| 1. D | 2. B | 3. B | 4. D | 5. B | 6. A | 7. A | 8. C | 9. A | 10. C |
| 11. B | 12. D | 13. A | 14. D | 15. B | 16. B | 17. A | 18. A | 19. C | 20. C |
| 21. B | 22. A | 23. A | 24. C | 25. D | 26. B | | | | |

Previous Years' Questions

- | | | | | | | | | | |
|-------|-------|-------|-------|-------|---------|-------|------|------|-------|
| 1. C | 2. A | 3. C | 4. A | 5. B | 6. A | 7. A | 8. A | 9. A | 10. D |
| 11. B | 12. C | 13. D | 14. B | 15. D | 16. 300 | 17. B | | | |